



รายงานวิจัยฉบับสมบูรณ์

โครงการผลของโลหะทรานซิชันที่แตกต่างกันกับสมบัติเชิง อิเล็กทรอนิกส์และสมบัติเชิงกลของวัสดุกลุ่มโลหะทรานซิชัน เตตระโบไรด์ภายใต้ความดันสูง

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สัญญาเลขที่ TRG6080014

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> คมศิลป์ โคตมูล โรงเรียนมหิดลวิทยานุสรณ์

สนับสนุนโดยสำนักงานกองทุนสนับสนุนการวิจัยและ ต้นสังกัด (ความเห็นในรายงานนี้เป็นของผู้วิจัย สกว.และต้นสังกัดไม่จำเป็นต้องเห็นด้วยเสมอไป)

บทคัดย่อ

รหัสโครงการ : TRG6080014

ชื่อโครงการ: ผลของโลหะทรานซิชันที่แตกต่างกันกับสมบัติเชิงอิเล็กทรอนิกส์และ

สมบัติเชิงกลของวัสดุกลุ่มโลหะทรานซิชันเตตระโบไรด์ภายใต้ความดันสูง

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ระยะเวลาโครงการ : 2 ปี

ในโครงการวิจัยนี้ ได้ใช้ทฤษฎีความหนาแน่นเชิงฟังก์ชัน (Density fucntional theory, DFT) และระเบียบวิธีทางวิวัฒนาการ (Evolutionary algorithms) เพื่อพยากรณ์โครงสร้างของ ้วัสดุกลุ่มโลหะโบไรด์ที่อยู่ภายใต้ความดันสูง พบว่า ในวัสดุ RuB4 ได้พบโครงสร้างใหม่ภายใต้ ความดันสูง ได้แก่ โครงสร้างผลึกแบบ C2/c และ Immm เสถียรที่ความดัน 198 – 388 GPa และสูงกว่า 388 GPa ตามลำดับ เมื่อเปรียบเทียบกับวัสดุ FeB4 และ OsB4 ซึ่งเป็นวัสดุที่มีโลหะ หมู่เดียวกันและมีโครงสร้างภายใต้ความดันสูงเป็นสารกึ่งตัวนำ แต่ทั้งนี้ พบว่า โครงสร้างผลึก แบบ C2/c และ Immm ของวัสดุ RuB₄ มีสมบัติเป็นสารกึ่งโลหะและโลหะ ตามลำดับ ทำให้ ลำดับการเปลี่ยนวัฏภาคเชิงโครงสร้างภายใต้ความดันสูงของ RuB₄ แตกต่างไปจากวัสดุ FeB₄ และ OsB4 นอกจากนี้ ยังพบว่า ค่าความแข็งที่คำนวณตามโมเดลของ Chen ของวัสดุ RuB4 ยัง มีค่าน้อยกว่าความแข็งของวัสดุ FeB₄ และ OsB₄ อีกด้วย ความแข็งของโครงสร้างผลึกที่ความ ดันบรรยากาศของวัสดุ RuB₄ (*P6₃/mmc*) มีค่าประมาณ 18 GPa การคำนวน Electron localization function (ELF), Mulliken population analysis (MPA) และ projected crystal orbital Hamilton populations (pCOHP) เปิดเผยว่า ลักษณะการจัดเรียงตัวของอะตอมและ ความแข็งของพันธะโควาเลนซ์ ส่งผลโดยตรงกับความแข็งของวัสดุกลุ่มนี้ ผลที่ได้จากงานวิจัยนี้ สามารถนำมาเป็นพื้นฐานสำคัญในการออกแบบวัสดุที่มีความแข็งพิเศษ (superhard materials) ในวัสดุกลุ่มโลหะโบไรด์ นอกจากวัสดุ RuB_4 แล้ว ยังได้พยากรณ์โครงสร้างผลึกของวัสดุ $\mathsf{Li}_2\mathsf{O}_2$ ที่ความดัน 75 GPa ได้พบโครงสร้างผลึกแบบใหม่ คือ P2₁ ที่แตกต่างเล็กน้อยจากโครงสร้าง ผลึกแบบเดิมที่เคย P2₁/c ที่เคยเสนอมาในงานวิจัยก่อนหน้า ทั้งนี้ ได้ศึกษาและอธิบายอย่าง ละเอียดของการบิดเบี้ยวในโครงสร้างผลึกที่ความดันบรรยากาศ $P6_{s}/mmc$ ของวัสดุ $\operatorname{Li}_{2}\operatorname{O}_{2}$ ซึ่ง ส่งผลโดยตรงต่อช่องว่างแถบพลังงาน (Ennergy gap) ค่าสัดส่วน c/a

คำหลัก : ความแข็ง; ความดันสูง; การเปลี่ยนวัฏภาค; วัสดุโลหะโบไรด์; ลิเทียมเปอร์ ออกไซด์

Abstract

Project Code: TRG6080014

Project Title: Effects of transition metals on electronic and mechanical properties

of transition- metal tetraborides under high pressure

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Project Period: 2 years

Employing a systematic first-principles investigation with crystal structure searching based on an evolutionary algorithm, the novel high-pressure phases of RuB4 -- C2/c and Immm phases have been uncovered at 198 and 388 GPa, respectively. Interestingly, in comparison with FeB₄ and OsB₄, which have an analogous electronic and chemical structure with RuB₄, and have predicted high-pressure structures exhibiting a semiconducting phase, it is found that both the C2/c and Immm phases of RuB₄ are likely to be the metallic materials. The hardness of predicted phases of RuB₄ has also been calculated by using the empirical model of Chen. It is found that the hardness of ambient phase, P6₃/mmc, is about 18 GPa, which is relatively low comparing to those of FeB₄ and OsB₄. The nature of chemical bonding investigated by electron localization function (ELF), Mulliken population analysis (MPA) and projected crystal orbital Hamilton populations (pCOHP) calculations reveals that the atomic configurations and the degree of covalent bonding of the predicted phases are responsible for lower hardness compared to those of FeB4 and OsB4. The results of this work provide more understanding of the family of metal tetraboride for designing metalboride based hard/superhard materials. For Li₂O₂, P2₁ structure, which is slightly different from the previous reported $P2_{1}/c$ structure, has been proposed. The distortion in the ambient phase (P6₃/mmc structure) of Li₂O₂ reported in previous experiment has been investigated. The finding shows that the pressure dependences of band gap, c/a ratio, ELF and phonon dispersion reflect to the structural distortion.

Keywords : hardness; high pressure; phase transition; ruthenium tetraboride; lithium peroxide

1. Introduction to the research problem and its significance

Diamond is known as the hardest material which has bulk modulus (B_0) 443 GPa and Vickers hardness (H_v) 90 – 120 GPa [1]. It is well known that covalent bond of sp³ hybridization between carbon atoms results of that hardest state. Therefore, not diamond is only used in gems and jewelry industry but it is also utilized in hard industries such as hard material coating, cutting and drilling tools, and other advanced optical technologies. Due to high demand of diamond use in recent year, the alternative hard/superhard materials are finding for this purpose.

Transition-metal boride compound (TM-B) is a kind of materials exhibiting a hard/superhard material ($H_{\nu} \ge 40$ GPa) [2] because of a degree of directional covalent bonding of three dimensional (3D) boron network. Both experimental and theoretical studies on TMB₂ และ TMB₄ revealed that these materials potentially are the hard or superhard materials with having high bulk modulus and hardness. For instance, OsB₂ has B_0 = 395 GPa and H_v = 37 GPa, [3-4] WB₄ has B_0 = 339 GPa and H_v = 43 GPa [5-6]. Notably, iron tetraboride (FeB₄) has been proposed its ambient pressure phase (e.g. Pnnm) exhibits a superhard superconducting material [7-8]. By using first-principles investigations, it has been revealed the high pressure phases, which belong the tetragonal structures with space groups of I4₁/acd and P4₂/nmc [9]. These two tetragonal phases cloud possess the semiconducting and hard/superhard materials. Recently, osmium tetraboride (OsB₄) has been presented the transitions sequence up to 300 GPa [10]. At 11 GPa, the P4₂/nmc phase emerges in OsB₄ similarly corresponding to FeB₄ [9]. Those findings suggested both FeB₄ and OsB₄ process a metal-tosemiconductor phase transition. The semiconducting FeB₄ and OsB₄ phases combining of semiconductive and potential hard properties are contributed to be the strong directional covalent bondings of three-dimension (3D) boron network and the significant covalence of TM-B pairs. While theoretically compressing CrB4 which starts by the identical Pnnm phase with FeB4, but it did not encounter the high-pressure semiconducting phase [11]. It is important to remark that Fe and Os are in the same group of 8B element in periodic table that share the similar electronic configuration, as a result of the related transformation pathway under high pressure of FeB₄ and OsB4. However, still, there are some questions and controversies raised by previous investigations for the TM-B compounds. Those issues open to the gaps of research, for example; (i) CrB₄ has the same ambient phase with FeB₄ but why does it has different high-pressure pathways with FeB₄? And what is about the RuB₄? (ii) What are the effects of number and energy level of *d* electrons of transition metals on the crystal structures and relating properties of TMB₄ under high pressure? Therefore, it can be addressed to require more investigations in this material family being still needed to fulfill and make deeper understandings.

This project aims at theoretically investigating in high-pressure behaviors of the TMB₄ by considering effects of different transition metals (i.e. Fe, Ru, and Os) on crystal structures, mechanical properties, electronic properties, and high-pressure phase transitions. It would be expectedly guiding the high-pressure behavior and revealing possible applications by this material family.

2. Objectives

- 1. To investigate the atomic mechanism of different transition metals in the TMB_4s (TM = Fe Ru and Os) which influences to their crystal structures, mechanical properties, electronic properties and structural phase transition under high pressure.
- 2. To calculate and evaluate the crystal structures, mechanical properties, electronic properties and structural phase transition under high pressure that may suggest to the further applications of the TMB_4s .

3. Methodology

This project mainly employed density functional theory (DFT) within some platforms consisting of VASP [12] and CASTEP [13] codes. The standard functional GGA-PBE [14] will be used to perform the most calculations in this project. Moreover, the hybrid functions such as HSE06 [15] was also implemented for calculating some appropriate properties, i.e., electronic band structure. Convergences of energy cutoff and k-point meshes and other input values was carefully used in the calculations to ensure and verify the accuracy of the computational results, as well as, the findings will be compared with the available experimental results. The more detail of methodology in this study is following;

- 1. Reviewing the literatures relating to the TMB₄ materials, to find the research gaps leading to the question of; what is the influences of different transition metals on crystal structure, high pressure phase transition, and relative properties of the TMB₄s?
 - 2. Searching the crystal structures as a function of pressure of the novel TMB₄ materials using evolutionary algorithm, which is a searching method inspired

by biological evolution, for instance, randomness, mutation, selection, recombination, and reproduction. The candidates from searches are given from the optimization problem. The method performing in this project was based on USPEX code (Universal Structure Predictor: Evolutionary Xtalloraphy) [16] which is interfacing with VASP codes. To predict the crystal structures of a material under high pressure using evolutionary algorithm, only atomic recipe is an initial input of a process. Varying number of atoms is necessary to ensure that the obtained structure is the most stable or global structure at that pressure. The procedure of evolutionary algorithm is shown as Figure 1.

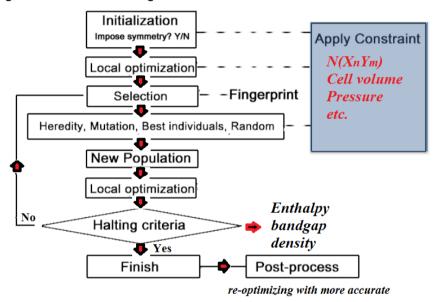


Figure 1: Flowchart of predicting crystal structure at certain condition by using evolutionary algorithm.

- 3. Calculating the stabilities of the crystal structures of the TMB₄s which consist of:
 - 3.1 Thermodynamic stability: Gibbs free energy is a value verifying that which structure is the most stable one comparing to others under a certain condition (Pressure and Temperature). For standard DFT calculation, the environment is constrained at zero Kelvin, therefore, Gibbs free energy reduces to enthalpy by this condition. To evaluate the stability of a material at above zero temperature, the phonon spectral energies (from 3.4) can be directly added into the enthalpy

part, then, it will construct the Gibbs free energy at given temperature of the material.

- 3.2 Formation energy: it can confirm that whether a given crystal structure is preferable existence than forming alloy of TM and boron or not.
- 3.3 Elastic stability: by considering elastic stiffness tensors, they can interpret to the stability of a material under loading according to Born stability criteria [15].
- 3.4 Dynamic stability: phonon dispersion indicates to the stability of a material resulting of atomic vibration though symmetry paths. A negative phonon frequency of a predicted crystal structure of material insists the instability of that crystal structure. Moreover, phonon dispersion also brings to accounting temperature effect in materials.
- 4. Calculating/evaluating the applicable properties of the TMB₄s such as elastic property, Vickers hardness, electron-phonon coupling, etc.

Vickers hardness: is a kind of hardness defining how resistant a solid is to various kinds of shape deformations under applying external stresses. In experimental method, the Vickers hardness of a material is measured by using diamond indenter. In theoretical method, Vickers hardness can be accessible by various methods. However, a conventional one proposed by Chen *et al*, (*Intermetallics*, **19** (2011) 1275) [17] where the Vickers hardness can be calculated from bulk (B) and shear (G) modulus of a crystal structure ($H_v = 2(k^2G)^{0.585} - 3$, where k = G/B is Pugh's modulus ratio). This model has been verified by comparing the calculated values with experiments of various materials, it showed that they were in good agreement with experimental results.

Electron-phonon coupling: is the value indicating the degree of interaction between lattice vibrations and electrons. This interaction is important not only in creating the phonon scattering of the electrons but also in the formation of Cooper pairs which is the cause of the superconductivity in material. The electron-phonon coupling is implemented within some DFT calculation platforms (such as Quantum Espresso). Critical temperature (T_c) can be computed by the Allen and Dynes formula [18] (the modified McMillan formula)

$$T_C = \frac{\omega_{\log}}{1.2} \exp \left[-\frac{1.04(1+\lambda)}{\lambda - \mu^* (1+0.62\lambda)} \right]$$

- where ω_{\log} , λ , and μ^* are logarithmic average frequency, electron-phonon coupling constant, and effective Coulomb interaction, respectively.
- 5. Calculating/analyzing to find the evidence that indicates what are the effects of transition metals in the TMB₄s under high pressure. The electronic structures of compounds by mean *d*-states of TM and *s-p* hybridization of boron will be investigated.
- 6. Summarizing and preparing manuscripts

4. Results and discussion

Part 1: Ruthenium tetraboride (RuB₄)

Firstly, the energetics of crystal structures of RuB₄ obtained from the crystal search and the analogous structures with other metal tetraborides are presented. It is found that, at low pressure, the three lowest enthalpy structures consisting of P6₃/mmc (MoB₄-type), Cmcm (OsB₄-type) and Cmc2₁ structures are carefully considered. After accurately optimizing these three structures, the P6₃/mmc structure exhibits the most stable phase at ambient pressure with as higher enthalpy respecting to that of the Cmcm structure. This result also insists that our prediction is reliable because it agrees with the previous prediction [19]. By increasing pressure up to 500 GPa, the relative enthalpies versus pressure of calculated phases are depicted in Figure 1. For high-pressure phases, a monoclinic structure, C2/c, is more stable than the ambient phase at pressure between 198 to 388 GPa, and then an orthorhombic phase, Immm, energetically prefers to be the high-pressure phase of RuB₄ under further compression up to 500 GPa.

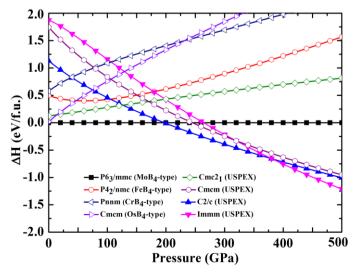


Figure1: Relative enthalpy of the calculated phases as a function of pressure with referenced to the P6₃/mmc phase.

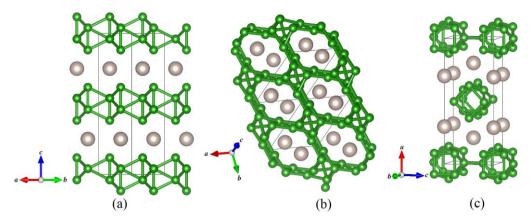


Figure 2: The atomic configurations of the predicted RuB₄ phases of (a) P6₃/mmc phase at 0 GPa (a = 2.945 Å and c = 10.578 Å with the Wyckoff positions of Ru: 2d(0.667, 0.333, 0.250) and B: 4f(0.667, 0.333, 0.040)), (b)C2/c phase at 200 GPa (a = 5.863 Å, b = 5.597 Å, c = 9.086 Å and β =158.85° with the Wyckoff positions of Ru: 4e(0, 0.381, 0.250) and B1: 8f(0.476,0.355,0.356) and B2: 8f(0.105, 0.604, 0.124)) and (c) the Immm phase at 0 GPa (a = 9.326 Å, b = 2.527 Å and c = 3.818 Å with the Wyckoff positions of Ru: 4e(0.2, 0.5, 0.5), B1: 8m(0.084, 0,0.206), B2: 4j(0, 0.5, 0.307) and B3: 4f(0.132, 0.5, 0)) .

After applying pressure, the characterization of B atoms has evolved. In other words, the networks of B atoms of the three phases surrounding the Ru atoms, transform into the different features. The atomic configurations of the AB stack of the P6₃/mmc phase, the honeycomb-like boron of the C2/c phase and the B_{12} cluster of the Immm phase are demonstrated in Figure2(a-c). In summary, the B atoms in RuB₄ prefer to form the stack or cluster rather than to interact with the Ru atoms. This result implies to the low hardness of this material. The volume (V₀), bulk modulus (B₀) and pressure derivative of bulk modulus at zero pressure (B'₀) fitted by Birch-Murnaghan EOS [20] of ambient and high-pressure phases of RuB₄, FeB₄ and OsB₄ are demonstrated in Table 2. The V₀s of the predicted phases of RuB₄ are larger than those of FeB₄ but smaller than those of OsB_4 , reflecting the fact that the V_0 of the TMB $_4$ depends on the size of transition metal. The B₀, which indicates the compressibility of materials, of the ambient phase of RuB₄ is approximately same with that of FeB₄ (Pnnm), but significantly lower than that of OsB₄ (Pmmn). However, the bulk moduli (B) of these three materials computing from the VRH approximation aline in the same trend of bulk moduli of their metal elements (B_{Fe}< B_{Ru}<B_{Os}). The difference between the bulk moduli of FeB₄ obtained by both methods is a main reason of contradict result. In this scenario, it is found that the bulk modulus of FeB₄ using VRH approximation is more reasonable because its value is closer to experimental value (252.5 GPa) [8] than that of EOS-fitting value.

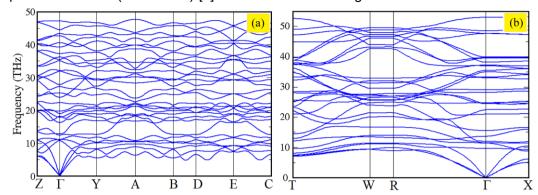


Figure 3: Phonon dispersion of the novel phases of RuB_4 consisting of (a) the C2/c at 200 GPa and (b) the Immm phase at 400 GPa.

Here the dynamical stability of novel phases, e.g. the C2/c and the Immm phases are examined, by performing phonon dispersion calculations. The results indicate that the C2/c and Immm phases at pressure 200 and 400 GPa, respectively, are the dynamically stable phases of RuB₄ as the absence of imaginary frequency (Figure 3(a,b)). Once the phonon dispersions of the P6₃/mmc phase was verified by the previous study.5 The established structural stability of the P63/mmc, the C2/c and the Immm phases provides us a guidance for investigating electronic structures. It is found that all the calculated phases exhibit the metallic phase with, nearly the Fermi level, the valence bands mainly dominated by 2p-B and 4d-Ru states but additional 2s-B state contributing the conduction bands as shown in Figure 4(a-c). Intriguingly, in contrast to the isoeletronic materials, FeB₄ and OsB₄, belonging a metal-to-semiconductor phase transition, RuB₄ has predicted nonsemiconducting phases. Although the semiconducting P42/nmc phase, which has been predicted in both FeB4 and OsB4, is calculated, it has higher enthalpy comparing to those of other candidates in RuB₄ (Figure 1). However the band structure of the C2/c phase which probably closes to the semiconductive feature is carefully considered. It has the double nodes at the Fermi level and across the M and Z points (Figure 4b). This band structure corresponds to a semimetal feature obviously supported by the node of total DOS at the Fermi level. The band structure calculated by using a hybrid HSE06 functional35 is also performed to verify this issue as shown in the inset of Figure 4b. The energy gap does not open in the HSE06 band structure and it confirms that the C2/c phase seems to be a semimetal as well.

Table 1: Calculated elastic constants (C_{ij}) of the predicted phases of RuB₄ at the stable pressures.

TMB ₄ -Phase	P(GPa)	(GPa) elastic constants (GPa)												
		C_{11}	C_{12}	C_{13}	C_{15}	C_{22}	C_{23}	C_{25}	C_{33}	C_{35}	C_{44}	C_{46}	C_{55}	C_{66}
RuB_4-P6_3/mmc	0	438	146	172					803		160			
RuB_4 - $P6_3/mmc$	150	1,077	520	600					1,632		398			
RuB_4 - $C2/c$	200	1,416	637	857	81	1,443	726	20	1,264	-44	444	-109	413	249
RuB_4 - $Immm$	400	2,284	1,250	$1,\!184$		2,192	1,244		2,037		540		491	483

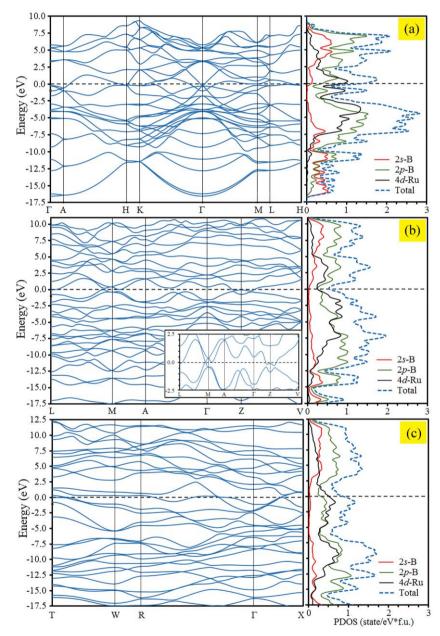


Figure 4: Band structure and partial density of state (PDOS) provided by using GGE-PBE with ultrasoft pseudopotential of (a) the $P6_3$ /mmc phase at 0 GPa, (b) the C2/c phase at 200 GPa (the inset is its band structure of around the Fermi energy using HSE06 calculation), (c) the Immm phase at 400 GPa.

Table 2: Illustration of calculated bulk modulus (B), shear modulus (G), Young's modulus (E), the Vickers hardness (H_v), and volume (V_0), bulk modulus (B_0) and pressure derivative of bulk modulus at zero pressure (B_0) fitted by Birch-Murnaghan EOS.

	Р		Moduli(GPa)			H_v	EOS fitting paramet		
TMB_4 -Phase	(GPa)	В	G	\mathbf{E}	G/B	(GPa)	$V_0(A^3)$	$B_0(GPa)$	$\mathrm{B}_{\mathrm{0}}^{\prime}$
RuB_4-P6_3/mmc	0	284	168	421	0.59	18.7	39.7	271	3.84
RuB_4 - $P6_3/mmc$	150	785	345	903	0.44				
RuB_4 - $C2/c$	0	281	111	294	0.40	7.6	38.3	286	3.86
RuB_4 - $C2/c$	200	950	325	875	0.34				
RuB_{4} - $Immm$	0	188	131	319	0.70	19.7	39.0	223	4.24
RuB_{4} - $Immm$	400	1536	488	1323	0.32				
FeB_4 - $Pnnm$	0	261	207	491	0.79	31.5	35.8	270	3.64
FeB_4 - $P4_2/nmc$	0	316	253	599	0.80	36.3	33.8	307	3.95
FeB_{4} - I_{41}/acd	0	314	272	633	0.87	41.9	33.8	312	3.87
OsB_4 - $Pmmn$	0	293	217	522	0.74	29.7	41.1	296	3.95
OsB_4 - $P4_2/nmc$	0	330	242	593	0.73	31.5	39.9	331	3.92

The elastic constants C_{ii} of the predicted phases of RuB₄ are listed in Table 1. These constants can be used to indicate the elastic stability and mechanical properties of solids. By using elastic stability criterion of Born the necessary and sufficient conditions of each crystal system were listed in the literatures [21,22]. It is found that all calculated phases of RuB₄ are elastically stable under their own conditions at stable pressures. In Table 2, in order to calculate the H_{ν} of the predicted phases, the bulk modulus (B), shear modulus (G) and Young's modulus (E) are estimated by using the VRH approximation. Based on the Chen's model, the H_v would dominantly depend on the magnitudes of G/B and G. It is found that most of G/B and G of RuB4 phases are much lower than those of the selected phases of FeB4 and OsB4, reflecting the lower Hv of RuB4 comparing to the isoelectronic materials as well. At 0 GPa, the Hvs of the P63/mmc, C2/c and the Immm phases are calculated to be 18.7, 7.6 and 19.7 GPa, respectively, mentioning that the predicted phases of RuB4 are not the hard material which has the minimal criteria of 20 GPa. As previous mentioning, the preference of forming boron stacking and clustering structures which have the lower G/B and G than those of the 3D networking metal-boron structures of FeB₄ and OsB₄ [9,10]. This finding could be directly explained by the atomic configurations of its individual structure which lead to the nature of chemical bonding.

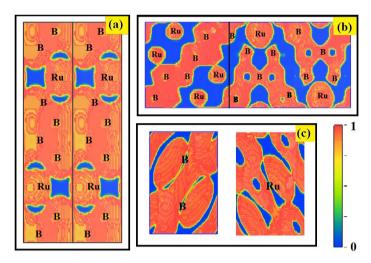


Figure 5: Visualizations of electron localization function (ELF) of (a) the P63/mmc phase at 0 GPa in the plane perpendicular to [100] direction, (b) C2/c phase at 200 in the plane perpendicular to [110] direction and (c) Immm phase at 400 in the planes perpendicular to [100] direction.

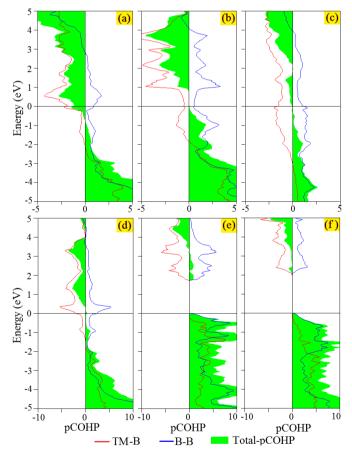


Figure 6: Plot of the projected crystal orbital Hamilton populations (pCOHP) versus energy of the predicted phases of RuB_4 and the selected phases of FeB_4 and OsB_4 consisting of (a) the RuB_4 -P6₃/mmc phase at 0 GPa, (b) the RuB_4 -C2/c phase at 200 GPa, (c) the RuB_4 -Immm phase at 400, (d) the FeB_4 -Pnnm, (e) the FeB_4 -P4₂/nmc and (f) the OsB_4 -P4₂/nmc.

The electron localization function (ELF) [23], Mulliken population analysis (MPA) [24] and projected crystal orbital hamilton populations (pCOHP) [25] which infer to the nature of chemical bonding of atoms, are calculated to elucidate the findings. In Figure 5 (a-c), the features of ELF of the P63/mmc, the C2/c and the Immm phases obviously show that the numbers of electrons prefer to localize at the interdistance of B atoms but they are very few at the ways connecting between Ru atoms to others. This finding points out the metallic state and the mechanical property of the calculated phases of RuB₄. By analyzing the MPA, it is found that the electron of 2s-B state is promoted into the 2p-B state about 1.0e as well as the donation of 5s-Ru state resulting of the different electronegativity of B and Ru atoms. Consequently, the increase of 2p-B and the electropositive charge of Ru atom are approximately 2.34e and +0.84e, 2.63e and +1.39e, 2.70e and +1.31e for the P63/mmc at 0 GPa, the C2/c at 200 GPa and the Immm at 400 GPa, respectively. These results indicate that there should be forming of sp2 and sp3 hybridizations within the electronic state of B atoms and forming ionic interaction between B and Ru atoms. The populations of B-B and Ru-B bondings are evaluated by using pCOHP calculation which interpret the calculated wavefunction into the covalent perspective, as obeyed in Figure6(a-c). It is found that, below the Fermi energy, all the populations of the B-B bondings are positive indicating there might be the high degrees of covalent bonds in the B-B pairs, but those of Ru-B bondings process the antibondings above -2 eV supporting the a few numbers of localized electron around the Ru atoms in ELF results. While magnifying at the Fermi level and above, the total of pCOHPs reveals that the population tails of antibondings of the P63/mmc and the Immm phases are over the Fermi level, which is a characteristic of metal, but, for the C2/c phase, there is a gap above the Fermi energy which implies to its semimetal state. The pCOHPs of the selected hard phases of FeB4 and OsB4 are illustrated in Figure 6(d-f), i.e., FeB₄-Pnnm (H_v=31.5 GPa), FeB₄-P4₂/nmc (H_v=36.3 GPa) and OsB₄-P4₂/nmc (H_v=31.5 GPa), to conceive what are the foundations of hardness for this material family. The metallic phase, FeB4-Pnnm, has the B-B bondings and Fe-B antibondings around the Fermi energy, while its Fe-B bondings are significantly stronger than those of B-B pairs at energy interval of -4 to -2 eV (Figure 6d) supporting the strong Fe-B covalent bonding in FeB₄-Pnnm.7 For the semiconducting phases, the P4₂/nmc phase of FeB₄ and OsB₄, have the high-density bondings for both B-B and Feor Os-B pairs at the occupied states (Figure 6(e-f)) indicating the strong and directional covalent bondings in these semiconducting phases. Based on the results of ELF, MPA and pCOHP associating with atom configurations, band structures and PDOSs, it is worth mentioning that the predicted phases of RuB4 are formed by frameworks of the B-B covalent bondings and the interlayer B-Ru ionic bonding and antibonding. Meanwhile the hard/superhard phases of FeB₄ and OsB₄ have been suggested by forming the strong and directional covalent bondings of both B-B and TM-B pairs. These should be resulting in the difference of inexistent semiconducting phase of RuB₄ comparing the FeB₄ and OsB₄, as well as their disadvantages in mechanical properties comparing to its family.

Part 2: Lithium peroxide (Li₂O₂)

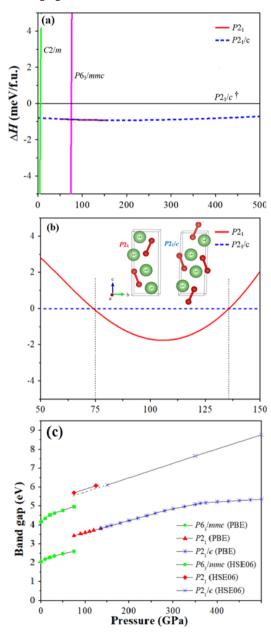


Figure 7: Pressure dependences of (a) relative enthalpies of the possible phases, (b) relative enthalpies of the $P2\sqrt{c}$ and $P2\sqrt{d}$ phases and (c) calculated band gaps by using PBE and HSE06 of the $P6\sqrt{mmc}$, $P2\sqrt{c}$ and

From the structural searching results for Li₂O₂ up to 500 GPa, the lowest enthalpy structures at different pressures have been found. At 0 and 50 GPa, the P63/mmc structure with 2 and 4 f.u. per cell has a lower enthalpy than the P1 structure (1 and 3 f.u.). This finding is in agreement with the previous experimental results revealing that the P6₃/mmc is stable up to 63 GPa [26,27]. Interestingly, the P2₁ (2 and 4 f.u.) structure has been found at 100 GPa, which has a lower enthalpy than the P2₁/c (2 and 4 f.u.) and C2/m (1 f.u.) structures at the same pressure. However, the P2₁ structure is not found at 200 GPa while the P2₁/c (2 f.u.) structure is still maintained up to 500 GPa. This result suggests that the P2₁ would probably be transformed to be the P2₁/c structure within a pressure range of 100-200 GPa. In Figure 7a and 7b, the transformation pathway based on the thermodynamic stability of Li2O2 under pressure up to 150 GPa is P6₃/mmc \rightarrow P2₁ \rightarrow P2₁/c with the transition pressures 75 and 136 GPa, respectively. The P2₁ and P2₁/c phases have the lower enthalpies than that of the P2₁/c[†] which was predicted by previous study. Figure 8c directs the tendencies of the band gaps of the stable phases as increased by increasing pressure for both PBE and HSE06 calculations.

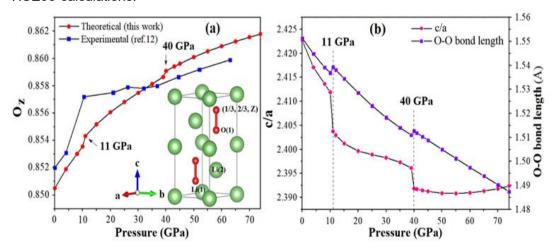


Figure 8: (a) The plot of the z-coordinate of the O atom (O_z) *versus* the pressure range of 0–74 GPa compared with the experimental results proposed by Dunuwille *et al.* [26] (b) The c/a ratio and O–O bond length in the $P6_3$ /mmc structure *versus* the same pressure range.

By increasing the pressure, we found that the z-coordinate of the O atom (O_z) for the P63/mmc structure was displaced and the O-O bond length decreased with the increasing pressure, as shown in Figure 8a and 8b, respectively. Surprisingly, the O_z

and O-O bond length significantly changed at pressures around 11 and 40 GPa. The atomic displacement of Oz from 10 GPa to 11 GPa is about 0.0057 Å, which is double its displacement on the trend line at 11 GPa. Likewise, the displacement of the Oz from 39 GPa to 40 GPa is 0.0031 Å, which istwice its displacement on the trend line at 40 GPa, resulting in the O-O bond length increase of about 0.0024 Å at 11 GPa and 0.0017 Å at 40 GPa with respect to its bonds at 10 and 39 GPa, respectively. These results are in line with the experimental results at ambient temperature proposed by Dunuwille et al.12 To investigate this situation, we evaluated the length of c, a, and the c/a ratio versus pressure and then considered the change in the interatomic distances of Li(1) – O(1), Li(2) –O(1), and Li(1) –Li(2). We found that the c/a ratio is abnormally collapsed around 11 and 40 GPa (see Figure 8b) because the lattice constant c has a higher reduction rate than that of lattice constant a (Figure 9a). The lattice constant c at 11 GPa deviates from its constant at the same pressure on the trend line about 0.018 Å and 0.009 Å at 40 GPa. In the same way, the reduction of lattice constant c from 10 GPa to 11 GPa is twice its constant from 39 GPa to 40 GPa like the reduction of the lattice constant a. In order to investigate the drastic shortening of the c-axis and the increased O-O bond lengths at 11 and 40 GPa, the electron localization function (ELF) of the P6₃/mmc structure has been calculated in the pressure range of 0-70 GPa. We found that the ELF isosurface values of the peroxide anion increase within the pressure ranges of 8-11 and 39-40 GPa (see Figure 9b) resulting in the softening of the O-O bond. When the O-O bonds along the c-axis soften, the c-axis weakens as well. Moreover, this collapses will have also significantly influenced the change in the interatomic distances of Li(1)-O(1), Li(2)-O(1), and Li(1)-Li(2) around 11 and 40 GPa.

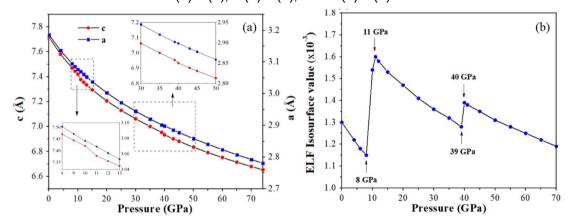


Figure 9: (a) Plot of the lattice constants (a and c) versus pressure (0-74 GPa). Insets represent the enlargement in the rectangular dashed lines. (b) Plot of the ELF isosurface value for the P6₃/mmc structure in the pressure range of 0-70 GPa.

5. Conclusions

In this project, the structural phase transitions and relating physical properties of RuB₄ and Li₂O₂ under high pressure were investigated using a systematic first-principles study. In RuB₄, the two novel phases of the C2/c and the Immm symmetry have been predicted at 198 and 388 GPa, respectively. The C2/c phase is confirmed to be a semimetal rather than a semiconductor. Therefore, the transformation pathway of RuB₄ under high pressure deviates from that of the isoelectronic materials, FeB₄ and OsB₄, which process the metal-to-semiconductor phase transition. The calculated H_vs of the predicted phases are much lower than those of the selected phases of FeB4 and OsB4. This could be explained by the atomic configurations and nature of chemical bondings of the predicted phases of RuB₄ which formed by frameworks of the B-B covalent bondings and the interlayer B-Ru ionic bondings and antibonding around the Fermi level. However, the results of this work provide a more understanding in a family of metal tetraborides for designing metal-boride based hard/superhard materials. For Li₂O₂, P2₁ structure, which is slightly different from the previous reported P2₁/c structure, has been proposed. The distortion in the ambient phase (P63/mmc structure) of Li2O2 reported in previous experiment has been investigated. The finding show that the pressure dependences of band gap, c/a ratio, ELF and phonon dispersion reflect to the structural distortion.

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 Oxygen-Rich Lithium Oxide Phases Formed at High Pressure for Potential
 Lithium-Air Battery Electrode. Adv. Sci. 2017, 4, 1600453.

Output จากโครงการวิจัยที่ได้รับทุนจาก สกว.

- 1. ผลงานตีพิมพ์ในวารสารวิชาการนานาชาติ (ระบุชื่อผู้แต่ง ชื่อเรื่อง ชื่อวารสาร ปี เล่มที่ เลขที่ และหน้า) หรือผลงานตามที่คาดไว้ในสัญญาโครงการ
- 1. **Komsilp Kotmool**, Prutthipong Tsuppayakorn-aek, Thanayut Kaewmaraya, Udomsilp Pinsook, Rajeev Ahuja and Thiti Bovornratanarak, "**Structural phase transitions**, **electronic properties and hardness of RuB**₄ **under high Pressure in comparison with FeB**₄ **and OsB**₄" submitted to *Journal of Physical Chemistry C* (Q1 journal with Impact factor of 4.309)
- 2. Pornmongkol Jimlim, **Komsilp Kotmool**, Udomsilp Pinsook, Suttichai Assabumrungrat, Rajeev Ahuja and Thiti Bovornratanaraks, "**Theoretical aspects in structural distortion and the electronic properties of lithium peroxide under high pressure**" *Phys. Chem. Chem. Phys.*, **2018**, 20, 9488. (Q1 journal with Impact factor of 3.567)
- 2. การนำผลงานวิจัยไปใช้ประโยชน์
 - เชิงพาณิชย์ (มีการนำไปผลิต/ขาย/ก่อให้เกิดรายได้ หรือมีการนำไปประยุกต์ใช้ โดยภาคธุรกิจ/บุคคลทั่วไป)

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- เชิงนโยบาย (มีการกำหนดนโยบายอิงงานวิจัย/เกิดมาตรการใหม่/เปลี่ยนแปลง ระเบียบข้อบังคับหรือวิธีทำงาน)

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- เชิงวิชาการ (มีการพัฒนาการเรียนการสอน/สร้างนักวิจัยใหม่)
 - สามารถนำงานวจิยัพื้นฐานไปใช้ในการประกอบการเรียนการสอนรายวิชา Many-body problem, Density functional theory and Solid-state physics
 - ในผลงานที่ 2 เป็นส่วนหนึ่งของวิทยานิพนธ์ในระดับปริญญาเอกของ ดร.พรมงคล จิ้มลิ้ม
- 3. อื่นๆ (เช่น ผลงานตีพิมพ์ในวารสารวิชาการในประเทศ การเสนอผลงานในที่ประชุม วิชาการ หนังสือ การจดสิทธิบัตร)

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ภาคผนวก

Structural phase transitions, electronic properties and hardness of RuB_4 under high pressure in comparison with FeB_4 and OsB_4

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Abstract

We have employed an evolutionary algorithm with first-principles calculations to investigate the pressure-induced structural evolution of RuB_4 up to 500 GPa. The ambient phase is predicted to be a hexagonal structure ($P6_3/mmc$). The novel phases consisting of monoclinic (C2/c) and orthorhombic (Immm) structures are proposed to be the high-pressure phases at the pressure intervals of 198 - 388 GPa and beyond 388 GPa, respectively. The stability of predicted phases is confirmed by both dynamic and elastic calculations. The electronic and mechanical properties of the predicted phases are evaluated and mainly discussed comparing to the isoelectronic metal tetraborides, i.e., FeB_4 and OsB_4 . In contrast to FeB_4 and OsB_4 , all the stable phases of RuB_4 are metal or semimetal, and any semiconducting phases do not emerge in the transformation pathway of RuB_4 . The nature of chemical bonding investigated by ELF, MPA and pCOHP calculations reveals that the atomic configurations and the degree of covalent bonding of the predicted phases are responsible for lower hardness compared to those of FeB_4 and OsB_4 . The results of this work provide more understanding of the family of metal tetraboride for designing metal-boride based hard/superhard materials.

Introduction

Transition-metal borides (TMBs) have drawn intensive attension because of superior hardness that could be utilized in high strength cutting and drilling tools. ^{1–9} Especially, TMB₄s, such as WB₄ and FeB₄, have been put to test and assert as the superhard materials with Vickers hardness (H_v) exceeding 40 GPa. ^{3,5} Moreover, their additional functionalities as superconductors ^{4–6} and semiconductors ^{4,6} have been reported.

For instance, iron tetraboride (FeB₄) exhibits a superhard and superconducting properties.^{4,5} Its high pressure phases (the tetragonal structures with space groups of $I4_1/acd$ and $P4_2/nmc$) are the semiconducting and hard/superhard materials.^{6,10} Recently, the structural transitions sequence of osmium tetraboride (OsB₄) has been presented up to 300 GPa.^{11,12} At 11 GPa, the $P4_2/nmc$ phase emerges in OsB₄ similarly resembling FeB₄.⁶ Both FeB₄

and OsB₄ undergo a metal-to-semiconductor phase transition. The semiconducting FeB₄ and OsB₄ phases offering potential hard properties are contributed by the strong directional covalent bondings of three-dimension (3D) boron networks and the significant covalency of TM-B pairs. While theoretically compressing CrB₄ which starts by the identical *Pnnm* phase with FeB₄, but it did not encounter the high-pressure semiconducting phase.¹³ It is important to remark that Fe and Os are in the group of 8B element in periodic table that share the analogous electronic configuration, as a result of the related transformation pathway under high pressure of FeB₄ and OsB₄.

Ruthenium (Ru) is one of group 8B element which share a fact with Fe and Os that they should maintain the hexagonal close packed (hcp) structure at extreme pressure and temperature. $^{14-16}$ To enhance the advantage of mechanical property, increasing stoichiometry of B content has been concentrated on Ru-B binary compounds. It was reported that RuB₂ has the Vicker's hardness (H_v) of 23.4 GPa. 17 The ambient phase of RuB₄ was predicted as a hexagonal structure (s.g. $P6_3/mmc$) with having the H_v value of 23.5 GPa. This phase could be synthesized under associating high pressure and temperature because it has lower stability compared with its relative with lower B concentrations and α -B at ambient pressure. 17 However, it is important to further investigate the stability and physical properties of this material under high pressure, in order to fulfill the physical understanding of the TMB₄s where TM is the 8B transition metals, i.e., Fe, Ru and Os. Therefore, the present study aims at theoretically investigating the high-pressure behaviors of RuB₄ up to 500 GPa. The unexpected finding that the transformation pathway of RuB₄ deviates from its isoelectronic materials (TM = Fe and Os) is focused and discussed using available tools based on density functional theory method.

Computational Methods

The heuristic evolutionary algorithm (EA) as implemented in USPEX^{18,19} interfacing with VASP code^{20,21} was comprehensively used to predict the global structures of RuB₄ at pressure range 0 - 500 GPa. The searches were performed by varying the cell size up to 4 formula units per cell (f.u./cell) and operated at 0, 50, 100, 200, 300, 400 and 500 GPa. The crystal structures of other TMB₄s, including $FeB_4^{\ 6}$ and $OsB_4^{\ 11}$ and $CrB_4^{\ 13}$ were also considered in the calculations for the comparative purposes. The CASTEP code²² employing the generalized gradient approximation functional (GGA-PBE)²⁴ and the ultrasoft pseudopotential²³ with the electronic configurations of Ru: $4s^24p^64d^75s^1$ and B: $2s^22p^1$ was used for the structural optimization. The cutoff energy of 500 eV and dense k-point meshes (spacing between k-points of $0.03\times2\pi$ Å⁻¹) were verified for all calculations to attain the energy convergence within 1 meV/f.u.. The Birch-Murnaghan equation of state (BM-EOS)²⁵ was used to fit the energy-volume curves to determine the thermodynamic stability phases. Phonon dispersion based on supercell and finite displacement approaches as implemented in Phonopy code 26 was performed to confirm the dynamic stability. Furthermore, the elastic constants (C_{ij}) were calculated to evaluate the elastic stability according to Born criteria. 27,28 Afterwards, bulk moduli (B), shear moduli (G) and Young's moduli (E) were calculated using the Voigt-Reuss-Hill approximation.²⁹ The Vickers hardness (H_v) was estimated using the empirical Chen's model, 30 H_{ν} = 2.0(k²G)^{0.585} - 3.0; k = G/B. The electron localization function (ELF), 31 Mulliken population analysis (MPA), ³² and projected crystal orbital Hamilton populations (pCOHP)³³ (using LOBSTER code³⁴) were used to elucidate the nature of chemical bonding of the stable phases.

Results and Discussion

We begin by presenting the energetics of crystal structures of RuB₄ obtained from the crystal search and the prototypical structures of analogous transition metal tetraborides. As

shown in Figure 1, $P6_3/mmc$ (MoB₄-type), Cmcm (OsB₄-type) and $Cmc2_1$ structures are energetically favorable at low pressure. After accurately optimizing these three structures, the $P6_3/mmc$ structure is the most stable phase at ambient pressure compared with the Cmcm structure agreeing with the reported prediction. ¹⁷ Meanwhile, monoclinic C2/c becomes stable phase at pressure between 198 to 388 GPa beyond which orthorhombic Immm energetically emerges as the high-pressure phase of RuB₄.

Table 1 assembles the crystallographic information of the stable phases and Figure 2 shows their atomic structures. The B atoms in the $P6_3/mmc$ phase are formed as separate layers stacked alternatively with Ru layers along the c-direction. On the other hands, the B atoms are forced to form connected networks and clusters in the C2/c and Immm phases because of the reduced atomic distances at high pressure. Moreover, the volume (V_0) , bulk modulus (B_0) and pressure derivative of bulk modulus at zero pressure (B'_0) fitted by Birch-Murnaghan EOS of the ambient and high-pressure phases of RuB₄, FeB₄ and OsB₄ are demonstrated in Table 2. The V₀ values of the predicted phases of RuB₄ are greater than those of FeB₄, but smaller than those of OsB₄, reflecting the fact that the V₀ parameter of TMB₄ depends on the atomic size of transition metals. We also found that B₀ which accounts for the compressibility of materials of the ambient phase of RuB₄ is approximately resembles that of FeB_4 (Pnnm), but significantly lower than that of OsB_4 (Pmmn). However, the bulk moduli (B) of these TMB₄s evaluated by the VRH approximation show in the same trend as the bulk moduli of the metal elements (i.e., $B_{Fe} < B_{Ru} < B_{Os}$). ^{14–16} The difference between the bulk moduli of FeB₄ obtained by both the methods is responsible for contradictory result. In this scenario, the bulk modulus of FeB₄ using VRH approximation is more reasonable because its value is closer to the experimental value (252.5 GPa)⁵ than that of the EOS-fitting value.

We here examined the dynamical stability of novel phases, e.g. the C2/c and the Immm phases, by performing phonon dispersion calculations. The results indicate that the C2/c and Immm phases at pressure 200 and 400 GPa, respectively, are the dynamically stable phases as the absence of imaginary frequency (Figure 3(a,b)). Once the phonon dispersions

of the $P6_3/mmc$ phase was verified by the previous study.⁵

The established structural stability of the $P6_3/mmc$, C2/c and Immm phases leads us to further investigate electronic structures. It is found that all the phases exhibit the metallic feature as shown in Figure 4(a-c). At nearly the Fermi level, the valence bands are mainly dominated by 2p-B and 4d-Ru states but additional 2s-B state contributes the conduction bands. Intriguingly, all the predicted phases of RuB₄ are non-semiconductor, differing from the reported metal-to-semiconductor phase transition in the isoeletronic materials, i.e., FeB₄ and OsB₄. Although the semiconducting $P4_2/nmc$ phase, which has been predicted in both FeB₄ and OsB₄, is considerably calculated, it processes higher enthalpy compared to those of other candidates in RuB₄ (see Figure 1). We, however, carefully consider the band structure of the C2/c phase which probably closes to the semiconductive feature. It has the double nodes at the Fermi level and across the M and Z points which corresponds to a semimetal feature (Figure 4b). The band structure by hybrid HSE06 functional 35 as shown in the inset of Figure 4b clarifies that the energy gap does not open.

Moreover, the elastic constants C_{ij} of the predicted phases of RuB₄ are listed in Table 1. These constants can be used to indicate the elastic stability and mechanical properties of solids. The elastic stability criteria of Born listed in the literatures ^{27,28} manifest that all the predicted phases of RuB₄ are elastically stable under their suitable pressure ranges. In Table 2, in order to estimate the H_v value of the predicted phases, the bulk modulus (B), shear modulus (G) and Young's modulus (E) are calculated by using the VRH approximation. Based on the Chen's model, a H_v value dominantly depends on the magnitudes of G/B and G. It is found that the most of G/B and G values of RuB₄ phases are much lower than those of the selected phases of FeB₄ and OsB₄, revealing that all the phases of RuB₄ are relatively softer than these of FeB₄ and OsB₄ as well. At 0 GPa, the H_v values of the P6₃/mmc, C2/c and the Immm phases are calculated to be 18.7, 7.6 and 19.7 GPa, respectively, indicating that the predicted phases of RuB₄ are not classified as a hard material according to the minimal criteria of 20 GPa of hardness. ³⁶ The softness of this material is attributed to the

tendency of forming planar stacking or clustering of B atoms, unlikely the strong 3D boron networking in FeB_4 and OsB_4 .^{6,11}

Furthermore, the electron localization function (ELF), shown in Figure 5(a-c), indicates that electrons in the $P6_3/mmc$, C2/c and Immm phases are delocalized to render the metallic feature. In addition, the spatial electron distributions between B atoms are covanlent-like, whereas there is the absence of electron cloud in the interstitial regions among Ru and B atom. Hence the Ru-B bonds are characterized as ionic. In particular, the degree of delocalization in the C2/c phase (H_v=13.8 GPa at P = 200 GPa) is relatively less than the $P6_3/mmc$ and Immm (H_v=16.6 GPa at P = 400 GPa) counterparts. This explains its lowest hardness as compared to others. Moreover, the ELFs of selected hard phases of FeB₄ and OsB_4 are comparatively illustrated in Figure 5(d-f), i.e., FeB_4 -Pnnm (H_v=31.5 GPa), $\text{FeB}_4\text{-}P4_2/nmc$ (H_v=36.3 GPa) and $\text{OsB}_4\text{-}P4_2/nmc$ (H_v=31.5 GPa), to conceive what are the foundations of hardness of this material family. It is very obvious to conclude that the selected FeB₄ and OsB₄ phases are harder than those of RuB₄ because Fe and Os atoms have higher potential of forming stronger bondings with B atoms compared to Ru atom, as illustrated by the larger localized electrons around Fe and Os atoms. Mulliken population analysis (MPA) further reveals that the electron of 2s-B state is promoted into the 2p-B state about 1.0e as well as the donation of 5s-Ru state facilitating by the different electronegativity of B and Ru atoms. Consequently, the increase of 2p-B and the electropositively charged Ru atom are approximately 2.34e and +0.84e, 2.63e and +1.39e, 2.70e and +1.31e for the $P6_3/mmc$ at 0 GPa, the C2/c at 200 GPa and the Immm at 400 GPa, respectively. These results indicate that there might be sp^2 and sp^3 hybridizations within the electronic states of B atoms and ionic interaction between B and Ru atoms. The populations of B-B and Ru-B bondings are evaluated by using pCOHP calculation which interpret the wave function into the covalent perspective, as shown in Figure 6(a-c). It is found that, below the Fermi energy, all the populations of the B-B bonds are positive indicating that there is the high degrees of covalent bonds in the B-B pairs, but those of Ru-B bonds process the antibondings above -2 eV supporting a few number of localized electrons around the Ru atoms in ELF results. The pCOHPs of the FeB₄ and OsB₄ are shown in Figure 6(d-f). The metallic phase FeB₄-Pnnm has the B-B bonds and Fe-B antibonds around the Fermi energy, while its Fe-B bonds are significantly stronger than those of B-B pairs at energy interval of -4 to -2 eV (Figure 6d) supporting the strong Fe-B covalent bonds in FeB₄-Pnnm.⁶ For the semiconducting phases, the $P4_2/nmc$ phase of FeB₄ and OsB₄, have the high-density bonds for both B-B and Fe-or Os-B pairs at the occupied states (Figure 6(e-f)) indicating the strong and directional covalent bonds in these semiconducting phases. It is worth emphasizing that the predicted phases of RuB₄ are formed by frameworks of the B-B covalent bondings and the interlayer B-Ru ionic bonding and antibonding. Meanwhile, the hard/superhard phases of FeB₄ and OsB₄ are originated from the strong and directional covalent bonds of both B-B and TM-B pairs. The differences in intrinsic chemical bonds of RuB₄ compared with FeB₄ and OsB₄ are responsible its metallic feature with reduced hardness.

Conclusion

We have investigated structural phase transitions and relating physical properties of RuB₄ under high pressure using the combination of evolutionary structural searching and density functional theory. The two novel phases C2/c and Immm have been predicted at 198 and 388 GPa, respectively. The C2/c phase is a semimetal rather than a semiconductor. Therefore, the transformation pathway of RuB₄ under compression intriguingly deviates from that of the isoelectronic FeB₄ and OsB₄, which undergo the metal-to-semiconductor phase transition. The calculated hardnesses of the predicted phases are comparatively lower than those of FeB₄ and OsB₄. This is attributed to the atomic configurations and nature of chemical bondings of the predicted RuB₄ phases in which frameworks of the B-B covalent bonds and the interlayer B-Ru ionic bonds are formed. Our findings emphasize the significant messages that the atomic arrangements and chemical bonds of B atoms in metal tetraborides play a

decisive role in their hardness.

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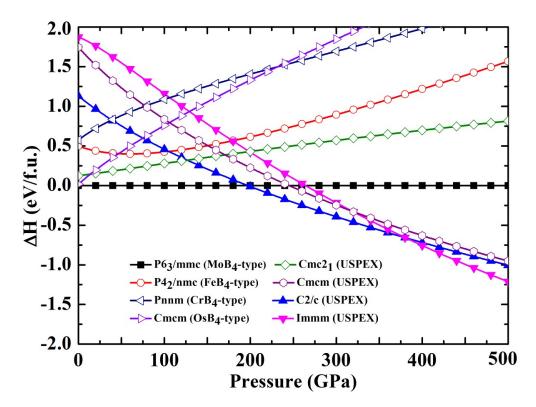


Figure 1: The relative enthalpy of the calculated phases as a function of pressure referenced to the $P6_3/mmc$ phase.

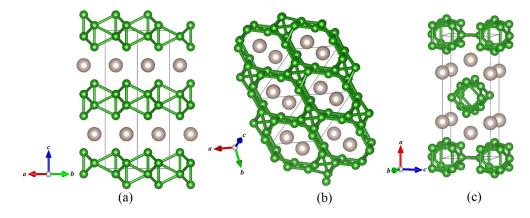


Figure 2: The atomic configurations of the predicted RuB₄ phases of (a) the $P6_3/mmc$ phase at 0 GPa, (b) the C2/c phase at 200 GPa and (c) the Immm phase at 0 GPa. Gray and green balls represent Ru and B atoms, respectively.

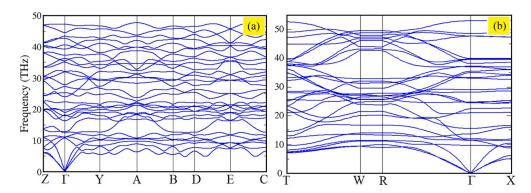


Figure 3: The phonon dispersion of the novel phases of RuB_4 consisting of (a) the C2/c at 200 GPa and (b) the Immm phase at 400 GPa.

Table 1: The lattice constants, atomic positions and elastic constants (C_{ij}) of the predicted phases of RuB₄ at the stable pressures.

Phase P(GPa) Lattice		Atomic positions Elastic constants (GPa)														
		constants		C_{11}	C_{12}	C_{13}	C_{15}	C_{22}	C_{23}	C_{25}	C_{33}	C_{35}	C_{44}	C_{46}	C_{55}	C_{66}
$P6_3/mmc$	0		Ru: $2d(2/3,1/3,1/4)$	438	146	172					803		160			
		c=10.578 Å	B:4f(2/3,1/3,0.04)													
C2/c	200	a=5.863 Å	Ru:4e(0,0.381,1/4)	1,416	637	857	81	1,443	726	20	1,264	-44	444	-109	413	249
		b=5.597 Å	B1:8f(0.476,0.355,0.356)													
		c=9.086 Å	B2:8f(0.105,0.604,0.124)													
		$\beta = 158.85^{\circ}$														
Immm	400	a=9.326 Å	Ru:4e(0.2,0.5,0.5)	2,284	1,250	1,184		2,192	1,244		2,037		540		491	483
		b=2.527 Å	B1:8m(0.084,0,0.206)													
		c=3.818 Å	B2:4j(0,0.5,0.307)													
			B3:4f(0.132,0.5,0)													

Table 2: The calculated bulk modulus (B), shear modulus (G), Young's modulus (E), the Vickers hardness (H_v), and volume (V_0), bulk modulus (B_0) and pressure derivative of bulk modulus at zero pressure (B'_0) fitted by Birch-Murnaghan EOS.

	Р		Mod	uli(GP	a)	H_v	EOS fit	ting param	eters
TMB_4 -Phase	(GPa)	В	G	E	G/B	(GPa)	$V_0(Å^3)$	B ₀ (GPa)	$\overline{\mathrm{B}_{0}^{\prime}}$
RuB_4-P6_3/mmc	0	284	168	421	0.59	18.7	39.7	271	3.84
RuB_4 - $P6_3/mmc$	150	785	345	903	0.44	20.4			
RuB_4 - $C2/c$	0	281	111	294	0.40	7.6	38.3	286	3.86
RuB_4 - $C2/c$	200	950	325	875	0.34	13.8			
RuB_4 - $Immm$	0	188	131	319	0.70	19.7	39.0	223	4.24
RuB_4 - $Immm$	400	1536	488	1323	0.32	16.6			
FeB_4 - $Pnnm$	0	261	207	491	0.79	31.5	35.8	270	3.64
FeB_4 - P_{42}/nmc	0	316	253	599	0.80	36.3	33.8	307	3.95
FeB_4 - I_{41}/acd	0	314	272	633	0.87	41.9	33.8	312	3.87
OsB_4 - $Pmmn$	0	293	217	522	0.74	29.7	41.1	296	3.95
OsB_4 - $P4_2/nmc$	0	330	242	593	0.73	31.5	39.9	331	3.92

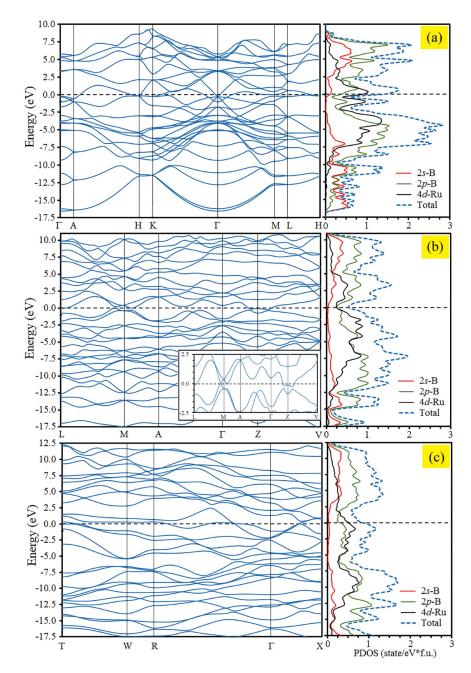


Figure 4: Band structure and partial density of state (PDOS) provided by using GGE-PBE with ultrasoft pseudopotential of (a) the $P6_3/mmc$ phase at 0 GPa, (b) the C2/c phase at 200 GPa (the inset is its band structure of around the Fermi energy using HSE06 calculation), (c) the Immm phase at 400 GPa.

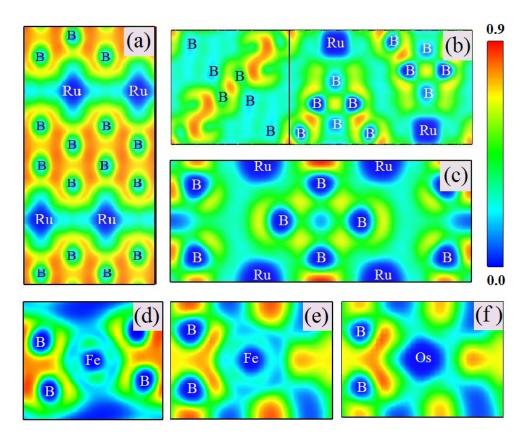


Figure 5: The electron localization function (ELF) of (a) the RuB₄- $P6_3/mmc$ phase at 0 GPa in (200) plane, (b) the C2/c phase at 200 in (100) and (001) planes, (c) the RuB₄-Immm phase at 400 in (001) plane, (d) the FeB₄-Pnnm in (001) plane, (e) the FeB₄- $P4_2/nmc$ in (200) plane, and (f) the OsB₄- $P4_2/nmc$ in (200) plane.

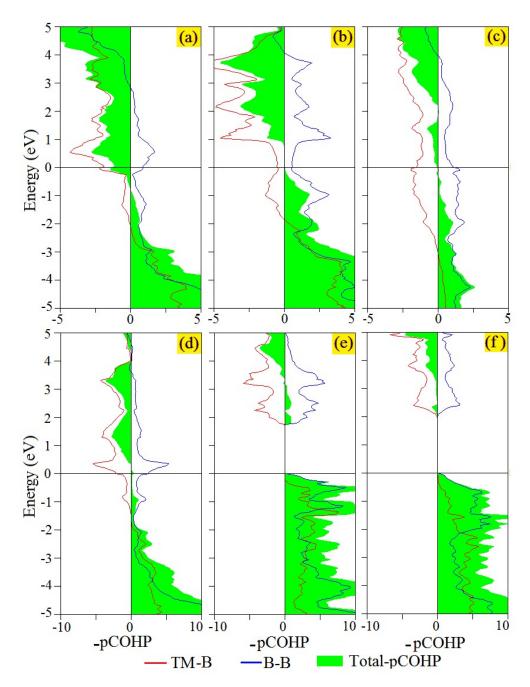


Figure 6: The projected crystal orbital Hamilton populations (pCOHP) of (a) the RuB₄- $P6_3/mmc$ phase at 0 GPa, (b) the RuB₄-C2/c phase at 200 GPa, (c) the RuB₄-Immm phase at 400, (d) the FeB₄-Pnnm, (e) the FeB₄- $P4_2/nmc$, and (f) the OsB₄- $P4_2/nmc$.



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Theoretical aspects in structural distortion and the electronic properties of lithium peroxide under high pressure†

The structural phase transition and electronic properties of Li_2O_2 under pressures up to 500 GPa have been investigated using first-principles calculations. Two new structural phase transitions have been proposed at pressures around 75 GPa from the $P6_3/mmc$ structure to the $P2_1$ structure and around 136 GPa from the $P2_1$ structure to the $P2_1/c$ structure. The calculated phonon spectra have confirmed the dynamical stability of these structures. The pressure dependence of the lattice dynamics, O-O bond length, and band gaps in Li_2O_2 have also been reported. The band gaps of the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures calculated by PBE and HSE06 have shown increasing trends with increasing pressure. Interestingly, the $P6_3/mmc$ band gap and c/a ratio have significantly decreased with the increasing O-O bond length and ELF value around 11 and 40 GPa. At these pressures, the phonon frequency of the O-O stretching modes has softened. This finding reveals the effects of structural distortion in three phases of Li_2O_2 . Our study provides structural understanding and the electronic properties of Li_2O_2 under high pressure, which might be useful for investigating the charge transport through Li_2O_2 in lithium—air batteries and CO_2 capture.

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1 Introduction

Lithium peroxide (Li_2O_2) is an oxygen-rich compound, which is used as an oxygen source for various applications.¹ It plays an

important role in air purification applications in sealed spaces, such as submarines, breathing apparatuses, and space capsules.^{2,3} Li₂O₂ can absorb CO₂ and release O₂ from its reaction.2 It is initially decomposed into Li2O and O2 at the temperature range of 340-348 °C.4 Importantly, Li₂O₂ is a discharged product of aprotic cells that is formed in the cathode of the lithium-air battery. This material has been studied in various contexts because the formation of Li2O2 blocks the recharging capability, which is responsible for the reduction in the lifetime and cyclability of the lithium-air battery.⁵ At ambient conditions, Fehér et al.⁶ and Föppl⁷ proposed hexagonal structures of Li_2O_2 with the same space group $(P\bar{6})$, but the lattice parameters and atomic positions of both reports were different. Cota et al. have confirmed the stability of those structures and optimised them using density functional theory calculations.8 They found that the optimised structure has lattice constants: a = 3.1830 Å and c = 7.7258 Å, which is a hexagonal structure with the $P6_3/mmc$ space group and corresponds to the structure proposed by Föppl. Moreover, Chan et al. have used the Rietveld refinement with the high-energy X-ray diffraction data and first-principles nonresonant inelastic X-ray scattering (NIXS) spectra to propose that $P6_3/mmc$ is the most compatible structure for Li_2O_2 . For previous high-pressure studies, Deng et al. have predicted the crystal structures of Li₂O₂ in the pressure range of 0-100 GPa using the particle swarm optimization algorithm (CALYPSO code). They used the Perdew-Burke-Ernzerhof (PBE) functional as implemented

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 $[\]dagger$ Electronic supplementary information (ESI) available: The structural parameters of the various structures at different pressures; the Mulliken charges of the Li and O atoms at different pressures; the plot of the lattice parameters and interatomic distances versus pressure; the phonon dispersion curves and partial phonon density of states (PDOSs) for the $P2_1/c$ structure at pressures of 75, 150, 300, and 500 GPa; the phonon dispersion curves and PDOSs for the $P2_1/c$ and $P2_1/c^{\dagger}$ structure at 150 GPa; the plot of the ELF isosurface value for the $P6_3/mmc$ structure; the density of states of Li and O at 5, 8, 11, 14, 38, 39, 40, and 41 GPa; the electron density maps and ELF for the various structures of Li $_2$ O $_2$; the crystal structures of Li $_2$ O $_2$ for three phases at different pressures. See DOI: 10.1039/c7cp07293g

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in the VASP (Vienna Ab initio simulation package) code to optimise the crystal structures and calculate electronic properties. They reported that the hexagonal structure (P63/mmc) of Li2O2 transforms to a monoclinic structure $(P2_1/c)$ at a pressure around 84 GPa. The band gap of Li2O2 has also been reported, which increases with increasing pressure. 10 Furthermore, Radin et al. reported that the stable surfaces of Li₂O₂ are half-metallic, whereas bulk Li₂O₂ is an insulator. 11 Recently, Dunuwille et al. have studied the crystal structure of Li₂O₂ up to 63 GPa using confocal micro-Raman spectroscopy and synchrotron X-ray diffraction. They found that the P6₃/mmc structure is maintained at 63 GPa. ¹² Very recently, Yang et al. have also investigated the structural stability of pure Li₂O₂ under high pressure at room temperature using XRD measurement. They found that Li₂O₂ is robustly stable up to 57 GPa. ¹³ In addition, the formation of holes in Li₂O₂ has been proposed by previous studies. 14-16 Hummelshøj et al. found that the lithium vacancies induced the formation of holes in the valence band of Li₂O₂. ¹⁴ Similarly, Ong et al. have also reported that a hole is formed in the π^* antibonding molecular orbital of the peroxide anion and proposed that the trapped hole can induce the local lattice distortion. 15 Besides, Garcia-Lastra et al. have analyzed the partial density of states of Li₂O₂ using the G₀W₀-corrected PBE calculations. They also found that a hole was formed in the π^* (p_x and p_y antibonding orbitals) antibonding orbital of the peroxide anion, which formed narrow bands at the top of the valence band. Furthermore, the π^* and σ^* (p_z antibonding orbital) orbitals of the peroxide anion mainly contributed in the valence and conduction bands, respectively, with a small contribution of the Li states. 16 These results indicate the existence of local distortion in the Li₂O₂ lattice.

The previous studies suggested that understanding of the structure and thermodynamic stability for Li₂O₂, Li₂O, and LiO₂ are fundamental for improving the performance of the lithium-air battery. 13,17 However, there are some issues for Li₂O₂ under high pressure that would need more investigation. For example, the effect of the local lattice distortion on the chemical bonding and electronic properties is not clarified, and its high-pressure phase transition pathway beyond the valid pressure is still incomplete. Therefore, we have used ab initio calculations based on density functional theory (DFT) formalism to investigate the detail of the structural phase transitions of defect-free Li₂O₂ under high pressure. The related properties including electronic band structure, phonon dispersion, O-O bond length, and electron localization function (ELF) have also been calculated. In addition, an evolutionary algorithm has been used to search for the higher pressure structures of Li₂O₂ up to 500 GPa to extend its transformation pathway.

2 Computational methods

A systematic *ab initio* evolutionary crystal prediction implemented within the USPEX (Universal Structure Predictor: Evolutionary Xtallography) code, 18,19 which interfaces to the VASP code with the PAW method, 20,21 has been used to search the global structures of Li_2O_2 at given pressures up to 500 GPa (*i.e.*, 0, 50, 100, 200, 300, and 500 GPa). The searches have been

performed by varying the cell size up to 4 formula units (f.u.) per cell (consisting of 8 Li and 8 O atoms). During the prediction, the number of initially randomized structures in the first generation was set at 30 structures. The next generation carried out 20 population structures using heredity and the mutations of the two lowest enthalpy structures of the previous generation by 60% and 20%, respectively, and the remaining 20% of the populations were obtained by randomisation. The searches would be done when the lowest enthalpy structure continuously survived within 25 generations. Then, the crystal structures obtained from the prediction at each pressure would be fully optimised by setting up a more accurate criterion. Structural optimisation was performed at pressures ranging from 0 to 500 GPa using an ab initio total energy calculations program, as implemented in the CASTEP (Cambridge Serial Total Energy Package) code.²² All optimisation would employ the BFGS algorithms, 23 the PBE exchange-correlation functional, 24 and the ultrasoft pseudopotentials for Li: 1s²2s¹ and O: 2s²2p⁴, which is implemented in the CASTEP code.²² The plane-wave kinetic energy cutoff of 700 eV and Monkhorst-Pack grid spacing of $0.04 \times 2\pi \, \mathring{A}^{-1}$ were used. The tolerance of calculation was set to 1.0×10^{-6} eV per atom for energy and 1.0×10^{-4} eV Å⁻¹ for maximum force. The electronic band structure and partial density of states have been calculated using the PBE24 and HSE0626 functionals. To obtain the equation of state parameters, the total energy (E) versus unit cell volume (V) relations of the various structures were fitted using the third-order Birch-Murnaghan equations of state. 27 Thus, the enthalpy (H) for the structure under pressure (P) can be calculated by the formula: H = E + PV. The dynamic stabilities of the calculated crystal structures, which are interpreted from the behaviour of phonon dispersion, have been performed using supercell and finite displacement approaches, as implemented in the Phonopy code.²⁸ VESTA software has been used for visualizing and analyzing the crystal structure.²⁹

3 Results and discussion

3.1 Crystal structure prediction

From the structural searching results for Li_2O_2 up to 500 GPa, the lowest enthalpy structures at different pressures have been found. At 0 and 50 GPa, the $P6_3/mmc$ structure with 2 and 4 f.u. per cell has a lower enthalpy than the $P\overline{1}$ structure (1 and 3 f.u.). This finding is in agreement with the previous experimental results revealing that the $P6_3/mmc$ is stable up to 63 GPa. Interestingly, the $P2_1$ (2 and 4 f.u.) structure has been found at 100 GPa, which has a lower enthalpy than the $P2_1/c$ (2 and 4 f.u.) and C2/m (1 f.u.) structures at the same pressure. However, the $P2_1$ structure is not found at 200 GPa while the $P2_1/c$ (2 f.u.) structure is still maintained up to 500 GPa. This result suggests that the $P2_1$ would probably be transformed to be the $P2_1/c$ structure within a pressure range of 100–200 GPa.

3.2 Structural phase transitions

The structural searching results show that the hexagonal structure $(P6_3/mmc)$ of Li_2O_2 with 2 f.u. at ambient pressure and zero

 $P6_3/mmc \rightarrow P2_1$, and the second transition pressure is above 136 GPa, $P2_1 \rightarrow P2_1/c$.

By increasing the pressure, we found that the z-coordinate of

temperature is the lowest enthalpy. The relaxed lattice constants are a = 3.1858 Å and c = 7.7182 Å, which are in agreement with the experimental values of 3.1692 and 7.7140 Å⁹ and the previous calculation values of 3.1830 and 7.7258 Å. 8 In order to investigate the structural phase transition of Li2O2 in the pressure range of 0-500 GPa, the enthalpy differences of the calculated structures *versus* pressure with respect to the $P2_1/c^{\dagger}$ structure predicted by Deng et al. 10 is shown in Fig. 1(a). The C2/m structure appears at very low pressure, and it disappears at a higher pressure. This is because the C2/m enthalpy is lower than that of the $P2_1/c^{\dagger}$ structure about 20 meV f.u.⁻¹ at ambient pressure, and its enthalpy becomes larger than that of the $P2_1/c^{\dagger}$ structure about 58 meV f.u.⁻¹ at 100 GPa (not shown). The first structural phase transition, which is that of the ambient phase, P63/mmc, is calculated at 75 GPa and transforms to another one as justified by the thermodynamic stability. The candidates at this pressure consist of the $P2_1$ and $P2_1/c$ structures with a small energy difference, which is due to the fact that they also have a very similar atomic configuration. According to the structure searching result, the $P2_1$ structure is not found at 200 GPa and the dynamical instability of the P2₁ structure occurs at 150 GPa due to the observation of a few negative phonon frequencies around the Γ -point (see Fig. 5(b)). Therefore, we refitted and plotted the enthalpy of the P2₁ structure with respect to the $P2_1/c$ structure versus the pressure range of 50-150 GPa, as shown in Fig. 1(b), to verify which structure is the more stable one. Around 75 and 135 GPa, the enthalpies of both structures are indistinguishable. However, at 100 GPa, the $P2_1$ structure is more stable than the $P2_1/c$ structure due to having a different enthalpy of 2 meV f.u.⁻¹. This finding corresponds to the structure searching result. In addition, the $P2_1$ enthalpy is initially higher than the $P2_1/c$ enthalpy around 136 GPa and increases to 2 meV f.u.⁻¹ at 150 GPa. These findings indicate that the P2₁ structure may exist in the pressure range of 75-135 GPa and transforms to the $P2_1/c$ structure at pressures beyond 136 GPa. Thus, it is possible to note that the first structural phase transition occurs at 75 GPa,

the O atom (O₂) for the P6₃/mmc structure was displaced and the O-O bond length decreased with the increasing pressure, as shown in Fig. 2(a) and (b), respectively. Surprisingly, the O_z and O-O bond length significantly changed at pressures around 11 and 40 GPa. The atomic displacement of O₂ from 10 GPa to 11 GPa is about 0.0057 Å, which is double its displacement on the trend line at 11 GPa. Likewise, the displacement of the Oz from 39 GPa to 40 GPa is 0.0031 Å, which is twice its displacement on the trend line at 40 GPa, resulting in the O-O bond length increase of about 0.0024 Å at 11 GPa and 0.0017 Å at 40 GPa with respect to its bonds at 10 and 39 GPa, respectively. These results are in line with the experimental results at ambient temperature proposed by Dunuwille et al.12 To investigate this situation, we evaluated the length of c, a, and the c/a ratio versus pressure and then considered the change in the interatomic distances of Li(1)-O(1), Li(2)–O(1), and Li(1)–Li(2). We found that the c/a ratio is abnormally collapsed around 11 and 40 GPa (see Fig. 2(b)) because the lattice constant c has a higher reduction rate than that of lattice constant a (Fig. S1, ESI \dagger). The lattice constant c at 11 GPa deviates from its constant at the same pressure on the trend line about 0.018 Å and 0.009 Å at 40 GPa. In the same way, the reduction of lattice constant c from 10 GPa to 11 GPa is twice its constant from 39 GPa to 40 GPa like the reduction of the lattice constant a. In order to investigate the drastic shortening of the c-axis and the increased O-O bond lengths at 11 and 40 GPa, the electron localization function (ELF) of the P63/mmc structure has been calculated in the pressure range of 0-70 GPa. We found that the ELF isosurface values of the peroxide anion increase within the pressure ranges of 8-11 and 39-40 GPa (see Fig. S7(b), ESI†) resulting in the softening of the O-O bond. When the O-O bonds along the c-axis soften, the c-axis weakens as well. Moreover, this collapses will have also significantly influenced the change in the interatomic distances of Li(1)-O(1), Li(2)-O(1), and Li(1)-Li(2) around 11 and 40 GPa, as shown in Fig. S2 (ESI†). These results

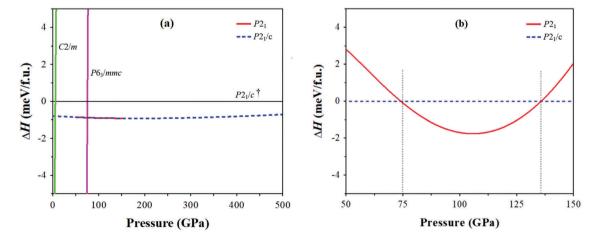


Fig. 1 (a) The enthalpy differences of the various structures with respect to the $P2_1/c$ structure predicted by Deng *et al.*¹⁰ (denoted as $P2_1/c^{\dagger}$ hereafter) in the pressure range of 0–500 GPa. (b) The enthalpy difference of the $P2_1$ structure with respect to the $P2_1/c$ structure in pressures ranging from 50 to 150 GPa. The vertical dashed lines represent the pressures at 75 and 135 GPa, respectively.

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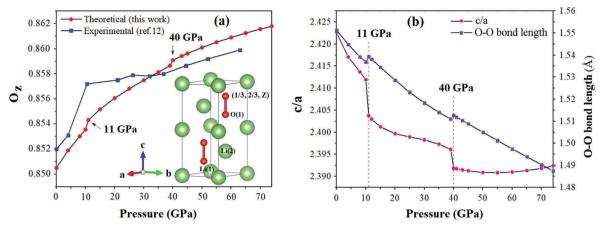


Fig. 2 (a) The plot of the z-coordinate of the O atom (O_z) versus the pressure range of 0–74 GPa compared with the experimental results proposed by Dunuwille et al. 12 (b) The c/a ratio and O-O bond length in the $P6_3/mmc$ structure versus the same pressure range.

show the existence of displacement in the Oz. Likewise, Wu et al. have also reported a small anisotropic compressibility in the P6₃/mmc structure of Li₂O₂. It is found that the bulk modulus along the c-axis (B_c) is higher than that along the a-axis (B_a) at zero pressure ($B_a/B_c = 0.589$) and, for that reason, the O-O bond along the c-axis is stronger than the Li-Li and Li-O bonds.30 However, our results suggest that the bulk modulus along the c-axis is lower than that along the a-axis in the pressure ranges of 10-11 GPa and 39-40 GPa. In addition, Dunuwille et al. have also reported the fluctuation in the c/a ratio, ¹² but an unusual collapse in the c/a, like our result, is not proposed. Thus, these results exhibit that the displacement in the Oz causes the dramatic collapse in the c/a ratio of the $P6_3/mmc$ structure.

At the transition pressure of 75 GPa, the Li and O atoms in the P6₃/mmc structure move to the new atomic positions in the P2₁ structure as shown in Fig. 3(b). The O-O bond length of 1.4592 Å and volume of the $P2_1$ structure are reduced by 1.85 and 2.87% from those of the P63/mmc structure, respectively. The average of the six nearest-neighbour Li-O distances (1.8335 Å)

in the $P2_1$ structure is longer than that of the distance (1.8080 Å) in the P63/mmc structure. Therefore, the phase transition at 75 GPa demonstrates that the electrostatic interaction between the Li and O atoms was decreased. Correspondingly, the ionicity of the P2₁ structure is less than that of the P63/mmc at 75 GPa (see Table S2, ESI \dagger). Moreover, the alignment of the peroxide anions in the $P2_1$ structure is tilted from the *c*-axis in the $P6_3/mmc$ structure about 20 degrees. In addition, the first structural phase transition has a significant difference with the previous predicted structure, that is the P63/mmc structure transforms to the monoclinic $(P2_1/c^{\dagger})$ structure at around 84 GPa. However, the $P2_1$ enthalpy is lower than that of the $P2_1/c^{\dagger}$ structure about 1 meV f.u.⁻¹ at 75 GPa, which might be significant at extremely low temperature. Consequently, the P21 structure should be a high-pressure phase of Li₂O₂ rather than the $P2_1/c^{\dagger}$ structure because the $P2_1$ structure has a lower enthalpy. The structural parameters of the P6₃/mmc, P2₁, $P2_1/c$, and $P2_1/c^{\dagger}$ structures are demonstrated in Table S1 (ESI †).

For the second structural phase transition, the Li and O atoms in the $P2_1$ structure move to the new atomic positions in

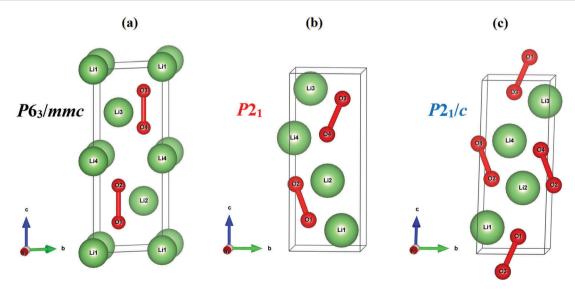


Fig. 3 The crystal structure of Li_2O_2 for the three phases: (a) $P6_3/mmc$ at 0 GPa, (b) $P2_1$ at 75 GPa, and (c) $P2_1/c$ at 136 GPa.

of similarity (Δ) of 0.445.

the $P2_1/c$ structure (see Fig. 3(c)). The O–O bond length and volume of the $P2_1/c$ and $P2_1$ structures at 136 GPa are insignificantly different. Similarly, the average of the six nearest-neighbour Li–O distances (1.7513 Å) in the $P2_1/c$ structure is insignificantly different to that of the distance (1.7512 Å) in the $P2_1$ structure. However, the peroxide anions are aligned on the (100) plane of the $P2_1/c$ structure, which tilted from the alignment in the $P2_1$ structure about 22 degrees. In addition, we found that the $P2_1/c$ enthalpy is slightly less than that of the $P2_1/c^{\dagger}$ structure about 1 meV f.u. $^{-1}$. In order to compare the structures, we have transformed the $P2_1/c$ structure to the most similar configuration of the $P2_1/c^{\dagger}$ structure using the COMPSTRU programme proposed by Flor $et al.^{38}$ The findings show that the $P2_1/c$ and $P2_1/c^{\dagger}$ structures at 150 GPa are different with the measurement

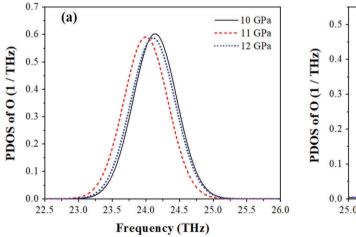
In order to investigate the driving force for the structural transitions, we have plotted the normalized lattice constants, angle between the a- and c-axes (β) , and interatomic distances versus pressure (0-500 GPa) for the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures, as shown in Fig. S3 (ESI†). The lattice constants a_0 , b_0 , and c_0 represent the lattice parameters of the $P6_3/mmc$ structure at ambient pressure. At the transition pressure of 75 GPa, the a- and b-axes are collapsed compared to the c-axis because the O-O bonds along the c-axis are stronger than the interactions of Li-Li in the ab-plane. Moreover, Fig. S3(c) (ESI†) demonstrates the dramatic reductions in the Li(1)-Li(2) and Li(2)-Li(2) distances upon the P6₃/mmc to P2₁ phase transition, which links to the alignment of the Li atoms in the P21 phase compared to the alternate stacking of the Li atoms in the $P6_3/mmc$ phase. The arrangement of the atoms in the $P6_3/mmc$ phase can be described as AcBcAbCbA, where the capital and small letters represent the Li and O atoms, respectively.8 Therefore, the driving force of the phase transition at 75 GPa is dictated by the alignment of the Li atoms in the P63/mmc phase resulting in the changes in the lattice parameters. For the $P2_1$ to $P2_1/c$ phase transition at 136 GPa, the a- and b-axes continuously decrease, yet the c-axis dramatically increases like β. Furthermore, unusual changes occur in the Li(1)-Li(2) and

Li(2)-Li(2) distances. These suggest that the driving force of the $P2_1$ to $P2_1/c$ transition is controlled by the alignment of the Li atoms in the $P2_1$ phase as well.

By considering the local distortion that occurred within the O-O units in the 75-500 GPa pressure range, the atomic displacement occurs in the xyz coordinates of the Li and O atoms (see Table S1, ESI†) and results in the O-O units tilting from the c-axis by angles of about 20, 22, 23, and 25 degrees at 75, 150, 300, and 500 GPa, respectively. For the evolution of the Li-O coordination, we found that the Li atom is coordinated to the six neighbouring O atoms at the same distance of 1.9962 Å, but the O atoms in the peroxide anion are coordinated to the six neighbouring Li atoms with distances of 2.1713 Å for O-Li(1) and 1.9962 Å for O-Li(2) at ambient pressure. At 74 GPa, these distances are changed to 1.8503 Å and 1.7695 Å, respectively. That is, the distances are reduced by 14.78% for O-Li(1) and 11.36% for O-Li(2). In addition, in the 75-500 GPa pressure range, the coordination numbers of the six Li and O atoms are the same with differences in the Li-O distances, such as 1.7769, 1.8481, 1.8224, 1.8629, 1.8374, 1.8533 Å at 75 GPa and 1.5609, 1.5487, 1.5539, 1.5541, 1.5593, 1.5735 Å at 500 GPa. These distances are reduced by 12.16, 16.20, 14.73, 16.58, 15.13, and 15.10%, respectively. It indicates that the Li-O coordination is strongly distorted with large variations of the individual Li-O distances within the same polyhedron and demonstrates the anisotropic distortion in the $P2_1$ and $P2_1/c$ phases of Li_2O_2 .

3.3 Phonon dispersion and partial phonon density of states

To investigate the dramatic change of the O–O bond lengths at pressures of 11 and 40 GPa in the $P6_3/mmc$ structure, as reported before, we have analyzed the partial phonon density of states (PDOSs) at pressures of 10, 11, 12, 39, 40, and 41 GPa, respectively. These PDOSs are shown in Fig. 4. The highest frequency phonon modes at a maximum density of phonon states, which represent the O–O stretching modes, are 24.13, 24.00, 24.10, 26.63, 26.56, and 26.65 THz, respectively. That is, at 11 and 40 GPa, the frequency of the O–O stretching modes significantly decreases and then increases by compression.



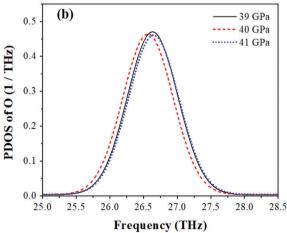


Fig. 4 The partial phonon density of states (PDOSs) of the O-O stretching modes for the $P6_3/mmc$ structure at: (a) 10-12 GPa and (b) 39-41 GPa.

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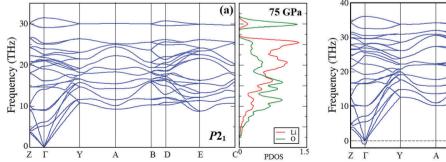
This result confirms the existence of the abnormal changes in the O-O bond length of the P6₃/mmc structure. Therefore, it is important to note that the pressures of 11 and 40 GPa soften the O-O bonds.

In order to verify the dynamic stability of the predicted structures $(P2_1 \text{ and } P2_1/c)$, we have calculated the phonon dispersion and PDOSs. We found that the phonon spectrum of the P2₁ has no imaginary phonon frequency at 75 GPa (Fig. 5(a)), but it has a few negative frequencies around the Γ -point at 150 GPa (Fig. 5(b)). This indicates that the $P2_1$ structure is dynamically stable at 75 GPa, but it is not stable at 150 GPa. For the $P2_1/c$ structure, we have also verified the dynamic stability at pressures of 75, 150, 300, and 500 GPa (see Fig. S4(a)-(d), ESI†), respectively. The phonon spectra of the high-pressure phases show the highest frequency phonon modes, which are mainly dominated by the O-O stretching modes. We found that the highest frequency phonon modes increase with increasing pressure from $\sim 32 \text{ THz} (1067 \text{ cm}^{-1}) \text{ at}$ 75 GPa to \sim 49 THz (1635 cm⁻¹) at 500 GPa. However, the Li₂O₂ stability has been confirmed with respect to the decomposition into Li₂O and O₂ in the pressure range of 0-100 GPa by Deng et al. 10 With the phonon dispersion and PDOSs in Fig. 5 and Fig. S4 (ESI†), a gap separating the low and high-frequency regimes appears at 75 GPa, and it is then decreased by further compression. The frequency gap that represents the characteristic decoupling of the peroxide anions from the rest of lattice³¹ appears in the P63/mmc and P21 phases. Lau et al.17 reported that the frequency gap of the P63/mmc phase at ambient pressure is about 16–23 THz. We believe that it also decreases by increasing pressures as appears in the P21 phase. Due to the pressure inducing increase in the electrostatic interaction of Li-O resulting in the Li-O phonon coupling, which contributes to a broader frequency range, the gaps could be decreased by compression.

To distinguish between the $P2_1/c$ and $P2_1/c^{\dagger}$ structures, we have compared their phonon spectra at the same pressure of 150 GPa (Fig. S5, ESI†). We have used an equivalent structure of the $P2_1/c^{\dagger}$ as the same Brillouin zone path in the calculations. The differences of phonon dispersion between the two structures are presented in the Y-A and E-C paths. The peak of the oxygen PDOSs of the $P2_1/c$ structure is slightly higher than the peak of the $P2_1/c^{\dagger}$ structure. Accordingly, it is sufficient to note that the $P2_1/c$ and $P2_1/c^{\dagger}$ structures are significantly different.

3.4 Electronic properties

To investigate the electronic band structure of Li₂O₂ under high pressure, we have calculated the band structures and partial density of states (PDOSs) using GGA-PBE as implemented in the CASTEP code. The band gaps have also been calculated using the hybrid functional, HSE06, implemented within the VASP code, 25 which is well-known to provide a more reliable quantity of band gap than that using the conventional functionals: GGA and LDA. Fig. 6(a) shows the PBE and HSE06 band gaps of various structures of Li₂O₂ in the pressure range of 0-500 GPa. At ambient pressure, the PBE band gap (2.05 eV) is lower than the band gap (4.18 eV, $\alpha = 0.25$) calculated by the HSE06. Nevertheless, our result is in good agreement with other calculated band gaps predicted using the PBE, HSE06, G₀W₀, and scGW methods (1.99, 4.19, 5.15, 6.37 eV).32 By increasing the pressure, the calculated band gaps of all three structures using both methods increase by the same trends. At the first transition pressure (75 GPa), the PBE band gap of P2₁ (3.43 eV) is higher than the P63/mmc band gap (2.60 eV) of about 0.8 eV. Similarly, the HSE06 band gap of $P2_1$ (5.70 eV) is higher than the P63/mmc band gap (4.98 eV) of about 0.7 eV. In the pressure range of 75-125 GPa, the maximum difference in the PBE band gap between the P21 and P21/c structures is approximately 5 meV. It is a very small difference, but the trend line of the HSE06 band gap (dashed line in Fig. 6(a)) implies the significant difference between the $P2_1$ and $P2_1/c$ band gaps. These findings insist that the tendency of band gaps calculated by the PBE functional would be reliable as well. Therefore, henceforth, the electronic band structures calculated using the PBE functional would be mainly discussed and the effects of pressure on the structural evolutions in Li₂O₂ monitored. In addition, we have compared the HSE06 band gap between the $P2_1/c$ and $P2_1/c^{\dagger}$ structures at 150 GPa. It is found that the HSE06 band gap of the $P2_1/c$ is less than that of the $P2_1/c^{\dagger}$ structure about 0.18 eV. This confirms the difference between the $P2_1/c$ and $P2_1/c^{\dagger}$ structures. Intriguingly, in the $P6_3/mmc$ structure, we found that the band gap has been significantly reduced by increasing the pressure at around 11 and 40 GPa, as shown in Fig. 6(b). The PBE band gaps reduce about 0.01 and 0.02 eV at 11 and 40 GPa with respect to the band gap at 10 and 39 GPa, respectively. Expectedly, by observing the O-O bond length in the 0-75 GPa pressure range, we found that the band



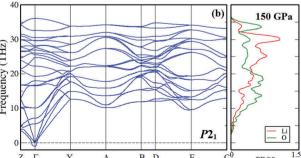


Fig. 5 The phonon dispersion curves and partial phonon density of states (PDOSs) for the P21 structure at: (a) 75 GPa, and (b) 150 GPa.

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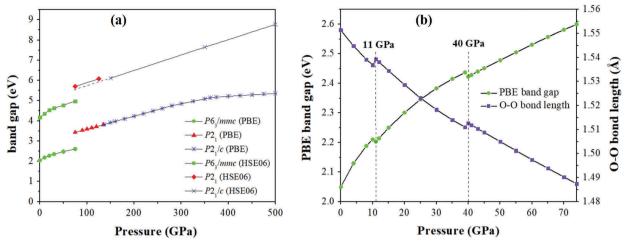


Fig. 6 (a) The PBE and HSE06 band gaps versus pressure for the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures. (b) The plot of the $P6_3/mmc$ band gap (PBE) and O-O bond length versus pressure (0-74 GPa).

gap increases with decreasing the O-O bond length. That is because the band gap exhibits the energy difference between the top of the valence band and the bottom of the conduction band. In the case of Li₂O₂, the O-O bond in the peroxide anion relates to the p-state of O, which mainly contributes in the valence and conduction bands. When the O-O bond in the peroxide anion is decreased by compression, the electrons are more tightly bound to the atom so that it requires more energy to remove. Therefore, the shorter O-O bond length provides the wider band gap. These indicate that the band gap of Li₂O₂ directly depends on the O-O bond length. Moreover, the band

gap suddenly decreases together with increasing the O-O bond length at pressures from 10 GPa to 11 GPa and 39 GPa to 40 GPa. These effects occur at the same pressures with a dramatic change in the c/a ratio as discussed before. Thus, it is obvious that the displacement in the z-coordinate of the O atoms results in a dramatic change of the band gap in the P63/mmc structure.

Fig. 7 illustrates the electronic band structure and partial density of states (PDOSs) for the three phases of Li₂O₂ at different pressures. By considering the PDOSs, it is seen that both the valence and conduction bands of the three phases are mainly contributed by the p-states of O and a few partial

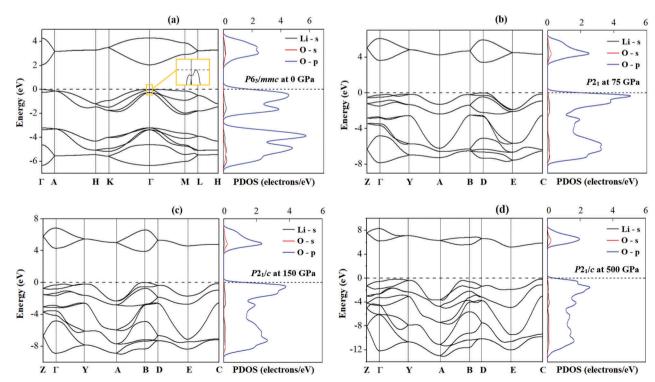


Fig. 7 The electronic band structure and partial density of states (PDOSs) for the structure of Li_2O_2 : (a) the $P6_3/mmc$ structure at 0 GPa, (b) the $P2_1$ structure at 75 GPa, and (c and d) the P2₁/c structure at 150 and 500 GPa, respectively. The dashed lines indicate the Fermi level, which is set to zero.

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contributions of the s-state of Li are observed. The band structures of the $P6_3/mmc$ structure at ambient pressure (Fig. 7(a)) exhibit the direct band gap (2.05 eV) at the Γ -point of the Brillouin zone. Interestingly, by magnifying around the Γ -point, the valence band maximum (VBM) is not exactly at the Γ -point, yet it is a point within the Γ -M path with a distance of

structures of the P63/mmc structure at ambient pressure (Fig. 7(a)) exhibit the direct band gap (2.05 eV) at the Γ -point of the Brillouin zone. Interestingly, by magnifying around the Γ -point, the valence band maximum (VBM) is not exactly at the k-point, yet it is a point within the Γ -M path with a distance of 0.660 beyond the Γ -point (see inset Fig. 7(a)). In the valence band of the high-pressure phases (see Fig. 7(b)-(d)), the conduction band has the main contribution in the p-states and small contribution in the s-state of O and a very small contribution in the s-states of Li. Furthermore, the band structures and PDOSs demonstrate that the valence band shifts to lower energy by increasing the pressure whereas the conduction band shifts to higher energy. That is why the band gaps increase with increasing pressure. In addition, the VBM of the P21 structure is at the D-point of the Brillouin zone until the transition pressure is reached, but the VBM of the $P2_1/c$ structure has changed from the B-point (\sim 150-280 GPa) to the C-point (\sim 280-500 GPa) of the Brillouin zone. These results obviously support the distortion of the Li₂O₂ lattice under high pressure, which corresponds to the changes in the atomic positions of Li₂O₂ under pressure (see Table S1, ESI†).

(h), (k)-(m) and (r), ESI†), the DOS energies of the s-states of Li and O and the p-states of O (except at 11 and 40 GPa) shift up with increasing pressure, but the DOS energies of the p-states of O at the bottom band shift down about 0.002 eV for 8-11 GPa and 0.01 eV for 39-40 GPa (Fig. S6(l) and (r), ESI†). Although the energy shifts are very small, the top valence bands shift to lower energies with increasing pressure as well. The result is the significant energy differences represented by the band gaps. Therefore, these lead to the decreasing band gaps at 11 and 40 GPa. Furthermore, the DOSs of the energies around 3.2 eV anomalously increase about 0.028 for 8-11 GPa as the DOSs around 3.4 eV increase about 0.014 for 39-40 GPa. This implies that the electrons occupied the conduction bands at 11 and 40 GPa more. The conduction band of Li_2O_2 represents the σ_p^* antibonding states of the peroxide anion. 16,39 Kang et al. have suggested that the molecular nature of the σ_p^* states brings about the characteristic electron lattice interaction in Li₂O₂, which conducts a delocalized electron in the σ_p^* states that is unstable against the formation of a small polaron. They found that the presence of an excess electron in Li2O2 leads to elongation of the O-O bond and results in it being less stable than that case with the polaron state.³⁹ Therefore, these support that if the delocalized electron occurs in the conduction band of the defect-free Li_2O_2 , the σ_p^* antibonding of the peroxide anion is strengthened, resulting in weakening of the O-O bonds at 11 and 40 GPa.

For the s-states of Li, the valence band energies decrease with increasing pressure, except at energy around -4.9 eV (see Fig. S6(a)-(e), ESI \dagger). The DOSs in the band energies of -3 to 0 eV decrease while the band energies of -8 to -3 eV increase, except at energy of about -5.9 eV for 38-41 GPa (Fig. S6(e), ESI†). Unusually, the DOSs at energy around -4.2 eV decreases at 5-8 GPa, but it increases at 8-11 GPa, and the energy shifts down about 0.04 eV (Fig. S6(b), ESI†). Conversely, the DOSs at energy of about -4.9 eV at 39-40 GPa increases to double that of the change at 38-39 GPa, and the energy shifts up about 0.02 eV (Fig. S6(d), ESI†). In the same way, the DOSs at energy of about -5.9 eV at 39-40 GPa decreases to double that of the change at 38-39 GPa, and the energy shifts up about 0.01 eV (Fig. S6(e), ESI†). Due to the energy step in the DOSs being 0.01 eV, this energy change is significant. Similarly, the band energies of the s-states of O decrease with increasing pressure, except at energy around -4.9 eV (see Fig. S6(f)-(j), ESI†). The DOSs at energy around -4.2 eV increase with increasing pressure and the change of the DOSs at 8-11 GPa increases to double that of the change at 5-8 GPa, and the energy shifts down about 0.04 eV. (Fig. S6(g), ESI†). Moreover, the DOSs at energy of -4.9 eV at 39 GPa is less than that at 40 GPa about 0.03 eV, but the change in the DOSs is very small (Fig. S6(i), ESI†). In addition, the DOSs at energy around -5.8 eV at 39-40 GPa decreases to double that of the change at 38-39 GPa, but the energy change is insignificant (Fig. S6(j), ESI†). For the p-states of O, the energies in the valence bands and their DOSs decrease with increasing pressure (see Fig. S6(k)-(q), ESI†). Due to the valence and conduction bands of the s-state of Li and the s- and p-states of O almost entirely overlapping, forming the σ -bond in Li₂O₂, it is possible to transfer electrons between the states of Li and O at the same energy level. As a result, the significant changes of the DOSs suggest that the transfer of electrons between the states of Li and O likely occur at the

In order to investigate the charge transfer in the P6₃/mmc structure, we have performed the Mulliken population analysis as implemented in the CASTEP. 33,34 We found that the Mulliken charges of Li(1)-Li(2) are 0.99|e|, 0.77|e| for Li(3)-Li(4) and -0.88|e| for O(1)-O(4) at ambient pressure, as shown in Table S2 (ESI†). These values are the same as reported by Deng et al. 10 Moreover, the structure of Li₂O₂ is anisotropic, that is the O atoms in the peroxide anion is coordinated to six neighbouring Li atoms with distances of 2.1713 Å for O-Li(1)/Li(2) and 1.9962 Å for O-Li(3)/Li(4) (see Fig. S10(a), ESI†). Therefore, the electrostatic interactions between O and Li for the O-Li(1)/Li(2) is stronger than that of the O-Li(3)/Li(4). These suggest that the atomic charges on the Li(1) and Li(2) are equal, but it is different to that of Li(3) and Li(4). Furthermore, we know that the Li and O atoms in Li_2O_2 have oxidation states of +1 and -1, respectively. So, it possible to note that the formation of Li₂O₂ has anisotropic charge transfers from O to Li: -0.48|e| to Li(1)-Li(4); -0.02|e| to Li(1)-Li(2), and -0.46|e| for Li(3)-Li(4).

By increasing the pressure from 0 GPa to 70 GPa, the Mulliken charges of the O(1)–O(4) and Li(1)–Li(2) increase from -0.88|e| to -0.93|e| and 0.99|e| to 1.10|e|, respectively. Conversely, the charges of the Li(3) and Li(4) decrease from 0.77|e| to 0.75|e|. Moreover, the O–Li(1)/Li(2) and O–Li(3)/Li(4) distances change from 2.1713 Å and 1.9962 Å at ambient pressure to 1.8587 Å and 1.7763 Å at 70 GPa, respectively. These demonstrate that the electrostatic interactions between O and

Li for the O-Li(1)/Li(2) increase more than that of the O-Li(3)/ Li(4) with the increasing pressure. Consequently, the pressure induces the changes in the electrostatic interactions of the O-Li(1)/Li(2) and O-Li(3)/Li(4) resulting in the variation in the Mulliken charges with pressure, which suggests charge transfers in Li₂O₂ under pressure. The pressure-dependent evolution of these charge transfers suggests that the Li₂O₂ compound is becoming more ionic. In order to measure the ionicity, we have calculated the effective ionic valence as proposed by Segall et al., which is defined as the difference between the formal ionic charge and the Mulliken charge on the anion species in the crystal.34 We found that the effective ionic valence is reduced from 0.12|e| at 0 GPa to 0.07|e| at 70 GPa, which indicates the increasing levels of ionic character. Unfortunately, we found that the resolution of the Mulliken charges calculation was not sufficient to distinguish the discontinuities at 11 and 40 GPa. That is the changes of the electron number in the PDOSs are less than 0.01 whereas the resolution of the Mulliken charges calculation is 0.01e. However, we have described the anomalies at 11 and 40 GPa using the PDOS

In addition, we not only found the transfer of charges in the $P2_1$ and $P2_1/c$ structures, we also found that the magnitude of the Mulliken charges of the O and Li atoms are the same, and it increases from 0.90|e| at 75 GPa to 0.95|e| at 500 GPa. This suggests that the oxidation state of the O atoms in the high-pressure phases approaches -1, supporting the stability of the peroxide group in Li_2O_2 under pressures of up to 500 GPa.

evolution with pressure as discussed before.

To investigate the effect of pressure on the chemical bonding of the $P6_3/mmc$ structure in the pressure range of 0–70 GPa, we have calculated the electron localization function (ELF)^{35,36} as implemented in the CASTEP,²² which provides a useful qualitative description of chemical bonding.³⁷ We found that the ELF isosurface value has a zig-zag feature with increasing pressure that it suddenly increases at the same range of the dramatic change in the O–O bond length and band gaps 8–11 GPa and 39–40 GPa as shown in Fig. S7(b) (ESI†). It demonstrates that the pressure induces the increase of electron localization resulting in the increase of the O–O bond lengths in the pressure range of 10–11 GPa and 39–40 GPa, and the change of the ELF value is significantly related to changing the DOSs of Li and O as well.

In addition, we have also plotted the electron density maps and ELFs of the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures at the pressures of 0, 75, 150, and 500 GPa, as shown in Fig. S8 and S9 (ESI \dagger). The maps exhibit the O–O and Li–O bonds at the different pressures. The ELFs reveal that the electron is highly localized in the covalent bonds of the O–O peroxide group, which corresponds to the DOS results that the electrons mainly contribute in the p-states of O. These results confirm the existence of the peroxide group up to 500 GPa and clearly exhibit the Li–O and O–O single bonds, which illustrates the bonds in the three phases of Li₂O₂ structures (see Fig. S10, ESI \dagger).

4 Conclusions

In this work, we have predicted the new structural phase transition and electronic properties of Li₂O₂ under pressures

up to 500 GPa using first-principles calculations. The $P6_3/mmc \rightarrow$ $P2_1$ and $P2_1 \rightarrow P2_1/c$ phase transitions have been predicted at pressures around 75 and 136 GPa, respectively. These structures have been confirmed by the dynamical stability seen in the phonon calculations. The ELF values exhibit the existence of the peroxide group in Li₂O₂ up to 500 GPa. We have reported that the pressure induces the O-O bond length, lattice dynamics, band gaps, and transfer of charges in Li₂O₂. Interestingly, we found that the $P6_3/mmc$ band gap and c/a ratio have dramatically collapsed with increasing the O-O bond lengths and ELF isosurfaces values of the peroxide group around 11 and 40 GPa. In addition, the PDOSs and Mulliken charges of the O and Li atoms demonstrate the transfer of charges between the O and Li atoms of Li_2O_2 in the $P6_3/mmc$ phase. The pressure-dependent evolution of these charge transfers suggests that the Li2O2 compound is becoming more ionic. These results reveal the mechanism for maintaining the structural stability under pressure by the atomic displacements in Li₂O₂. Our results provide understanding about the behaviour of the peroxide group, structures and electronic properties of Li₂O₂ under high pressure, which might be useful for investigating the charge transport through Li₂O₂ in the lithium-air battery and CO2 capture.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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Electronic Supplementary Information (ESI):

Theoretical aspects in structural distortion and the electronic properties of lithium peroxide under high pressure

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Table S1. Structural parameters of Li₂O₂ for the $P6_3/mmc$, $P2_1$, $P2_1/c$, and $P2_1/c^{\dagger}$ structures **Table S2.** Mulliken charges of the Li and O atoms for the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures of Li₂O₂ at the different pressures. Figure S2. (a)-(b), (c)-(d), and (e)-(f) represent the interatomic distances of the Li(1)-O(1), **Figure S3.** (a) Plot of the normalized lattice constants *versus* pressure, (b) Plot of the β *versus* pressure, (c) Plot of the interatomic distance *versus* pressure, (d) the $P6_3/mmc$ structure at 0 GPa, (e) the $P2_1$ **Figure S4.** Phonon dispersion curves and partial phonon density of states (PDOSs) for the $P2_1/c$ Figure S5. Phonon dispersion curves and partial phonon density of states (PDOSs) for two structures of Figure S6. Partial density of states (PDOS) of Li and O for the P6₃/mmc structure at 5, 8, 11, 14, 38, 39, 40, and 41 GPa: (a)-(e) for the s-states of Li, (f)-(j) for the s-states of O, and (k)-(r)

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Table S1. Structural parameters of Li₂O₂ for the $P6_3/mmc$, $P2_1$, $P2_1/c$, and $P2_1/c^{\dagger}$ structures at the different pressures.

			Lattice	paramete	r						
Pressure	Structure				$90^{\circ}, \gamma = 120^{\circ}$	Atom	Site	Atomic coordinates			
(GPa)	Birdetare	$(P2_1, P2_1/c : a \neq b \neq c, \alpha = \gamma = 90^0, \beta \neq 90^0)$					Site .				
		a (Å)	b (Å)	c (Å)	β (degree)			X	у	Z	
0	DC /	2.1050	2.1050	7.7100	90.0000	Li(1)	2a	0.00000	0.00000	0.00000	
0	P6 ₃ /mmc	3.1858	3.1858	7.7182		Li(2)	2c	0.33333	0.66667	0.25000	
						O(1)	4f	0.33333	0.66667	0.64950	
10	DC /	2.0767	2.0767	7 4200	00.0000	Li(1)	2a	0.00000	0.00000	0.00000	
10	P63/mmc	3.0767	3.0767	7.4208	90.0000	Li(2)	2c	0.33333	0.66667	0.25000	
						O(1)	4f	0.33333	0.66667	0.64645	
1.1	DC /	2.0604	2.0604	7 2700	00.0000	Li(1)	2a	0.00000	0.00000	0.00000	
11	$P6_3/mmc$	3.0694	3.0694	7.3780	90.0000	Li(2)	2c	0.33333	0.66667	0.25000	
						O(1)	4f	0.33333	0.66667	0.64568	
20	D.C. /	2 0020	2 0020		00 0000	Li(1)	2a	0.00000	0.00000	0.00000	
39	P6 ₃ /mmc	2.9020	2.9020	6.9536	90.0000	Li(2)	2c	0.33333	0.66667	0.25000	
						O(1)	4f	0.33333	0.66667	0.64135	
40	D.C. /	2 0007	2 0007	6.0000		Li(1)	2a	0.00000	0.00000	0.00000	
40	P63/mmc	2.8987	2.8987	6.9332	90.0000	Li(2)	2c	0.33333	0.66667	0.25000	
						O(1)	4f	0.33333	0.66667	0.64091	
	D.C. /	0.5501	2.5501		00 0000	Li(1)	2a	0.00000	0.00000	0.00000	
75	P6 ₃ /mmc	2.7781	2.7781	6.6468	90.0000	Li(2)	2c	0.33333	0.66667	0.25000	
						O(1)	4f	0.33333	0.66667	0.63816	
			2.5942	6.4767	91.8505	Li(1)	2a	0.84403	0.72368	0.11400	
75	$P2_1$	2.5695				Li(2)	2a	0.65603	0.51017	0.38600	
, 3	1 21	2.5075	2.3712		71.0505	O(1)	2a	0.34300	0.21666	0.15252	
						O(2)	2a	0.15705	0.01719	0.34747	
75	$P2_{1}/c$	2.5695	2.5941	7.0454	113.2454	Li	4e	0.45790	0.89333	-0.13599	
73	121/0	2.3073	2.3741	7.0454	113.2434	O	4e	-0.00463	0.40036	-0.09748	
75	$P2_1/c$ †	$2_1/c^{\dagger}$ 6.4771	1 2.5941	6.8903	158.1169	Li	4e	0.72995	0.60668	0.09399	
73		0.4771				O	4e	0.19042	1.09963	-0.40707	
						Li(1)	2a	0.85698	0.72372	0.11396	
136	$P2_1$	2.4424	2.4876	6.1569	89.7118	Li(2)	2a	0.64303	0.51011	0.38604	
130						O(1)	2a	0.35399	0.22011	0.14973	
						O(2)	2a	0.14603	0.01376	0.35026	
136	$P2_{1}/c$	2.4423	2.4877	6.6119	111.3833	Li	4e	0.47094	0.89325	-0.13607	
130	12//0	2.4423	2.4077	0.0117	111.5055	O	4e	0.00379	0.39687	-0.10025	
136	$P2_1/c$ †	6.1570	2.4877	6.6353	158.4040	Li	4e	0.74306	0.60677	0.10702	
130	1 2/10	0.1370	2.4077	0.0555	130.4040	O	4e	0.20427	1.10314	-0.39600	
			4197 2.4701	6.1009		Li(1)	2a	0.85965	0.72409	0.11390	
150	$P2_1$	2.4197			89.2687	Li(2)	2a	0.64037	0.50973	0.38611	
130	1 21	2.4177	2.4701	0.1009	09.2007	O(1)	2a	0.35608	0.22093	0.14924	
						O(2)	2a	0.14394	0.01296	0.35076	
150	$P2_{1}/c$	2.4194	2.4703	6.5333	110.9788	Li	4e	0.47361	0.89276	-0.13616	
130		2.4194	2.4703	0.5555	110.9766	O	4e	0.00547	0.39595	-0.10074	
150	$P2_{1}/c$	6.1008	2.4703	6.5333	158.2667	Li	4e	0.52639	0.60724	0.89023	
130	(similar)∥	0.1000	2.4703	0.5555	130.2007	O	4e	0.99453	0.10405	0.39379	
150	$P2_1/c^{\dagger}$	6.1009	2.4703	6 5026	150 1716	Li	4e	0.74587	0.60726	0.10975	
130	1 21/0	0.1009	2.4703	6.5926	158.4716	O	4e	0.20690	1.10404	-0.39386	
200	D 2 : / a	2.2464	2 2 472	5.0542	107 5212	Li	4e	0.49472	0.88747	-0.13824	
300	$P2_{1}/c$	2.2464	2.3473	5.9562	107.5213	O	4e	0.01976	0.38790	-0.10386	
500	D2 /-	0 1174	2 2416	5 5702	105 4206	Li	4e	0.49349	0.61747	1.14122	
500	$P2_{1}/c$	2.1174	2.2416	5.5723	105.4396	O	4e	0.96991	0.11908	1.10491	

[†]Reference 10

||Structural parameters obtained by using COMPSTRU programme proposed by Flor et al³⁸.

Table S2. Mulliken charges of the Li and O atoms for the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures of Li_2O_2 at the different pressures. The charge spilling parameters for the $P6_3/mmc$, $P2_1$, and $P2_1/c$ structures are in the ranges of 0.80-0.83 %, 0.85-0.88 %, and 0.89-1.06 %, respectively. The effective ionic valences is calculated by using the difference between the formal ionic charge and the Mulliken charge on the anion species in the crystal proposed by Segall *et al.* 34

Pressure	Structure		Effective ionic *							
(GPa)		Li(1)	Li(2)	Li(3)	Li(4)	O(1)	O(2)	O(3)	O(4)	valences ($ e $)
0	P6 ₃ /mmc	0.99	0.99	0.77	0.77	-0.88	-0.88	-0.88	-0.88	0.12
O^{\dagger}	$P6_3/mmc^{\dagger}$	0.99	0.99	0.77	0.77	-0.88	-0.88	-0.88	-0.88	0.12
4	P6 ₃ /mmc	1.00	1.00	0.77	0.77	-0.88	-0.88	-0.88	-0.88	0.12
6	P6 ₃ /mmc	1.00	1.00	0.77	0.77	-0.88	-0.88	-0.88	-0.88	0.12
8	P6 ₃ /mmc	1.01	1.01	0.77	0.77	-0.89	-0.89	-0.89	-0.89	0.11
10	P6 ₃ /mmc	1.01	1.01	0.77	0.77	-0.89	-0.89	-0.89	-0.89	0.11
11	P6 ₃ /mmc	1.01	1.01	0.77	0.77	-0.89	-0.89	-0.89	-0.89	0.11
12	P6 ₃ /mmc	1.02	1.02	0.77	0.77	-0.89	-0.89	-0.89	-0.89	0.11
15	P6 ₃ /mmc	1.02	1.02	0.77	0.77	-0.89	-0.89	-0.89	-0.89	0.11
20	P6 ₃ /mmc	1.03	1.03	0.77	0.77	-0.90	-0.90	-0.90	-0.90	0.10
25	P6 ₃ /mmc	1.04	1.04	0.76	0.76	-0.90	-0.90	-0.90	-0.90	0.10
30	P6 ₃ /mmc	1.05	1.05	0.76	0.76	-0.91	-0.91	-0.91	-0.91	0.09
35	P6 ₃ /mmc	1.06	1.06	0.76	0.76	-0.91	-0.91	-0.91	-0.91	0.09
39	P6 ₃ /mmc	1.06	1.06	0.76	0.76	-0.91	-0.91	-0.91	-0.91	0.09
40	P6 ₃ /mmc	1.06	1.06	0.76	0.76	-0.91	-0.91	-0.91	-0.91	0.09
41	P6 ₃ /mmc	1.07	1.07	0.76	0.76	-0.91	-0.91	-0.91	-0.91	0.09
45	P6 ₃ /mmc	1.07	1.07	0.76	0.76	-0.92	-0.92	-0.92	-0.92	0.08
50	P6 ₃ /mmc	1.08	1.08	0.76	0.76	-0.92	-0.92	-0.92	-0.92	0.08
55	P6 ₃ /mmc	1.08	1.08	0.76	0.76	-0.92	-0.92	-0.92	-0.92	0.08
60	P6 ₃ /mmc	1.09	1.09	0.76	0.76	-0.92	-0.92	-0.92	-0.92	0.08
65	P63/mmc	1.10	1.10	0.76	0.76	-0.93	-0.93	-0.93	-0.93	0.07
70	P63/mmc	1.10	1.10	0.75	0.75	-0.93	-0.93	-0.93	-0.93	0.07
75	$P6_3/mmc$	1.11	1.11	0.75	0.75	-0.93	-0.93	-0.93	-0.93	0.07
75	$P2_{1}$	0.90	0.90	0.90	0.90	-0.90	-0.90	-0.90	-0.90	0.10
135	$P2_{1}$	0.92	0.92	0.92	0.92	-0.92	-0.92	-0.92	-0.92	0.08
136	$P2_{1}/c$	0.92	0.92	0.92	0.92	-0.92	-0.92	-0.92	-0.92	0.08
150	$P2_{1}/c$	0.92	0.92	0.92	0.92	-0.92	-0.92	-0.92	-0.92	0.08
300	$P2_{1}/c$	0.94	0.94	0.94	0.94	-0.94	-0.94	-0.94	-0.94	0.06
500	$P2_{1}/c$	0.95	0.95	0.95	0.95	-0.95	-0.95	-0.95	-0.95	0.05

[†]Reference 10

^{*}Reference 34

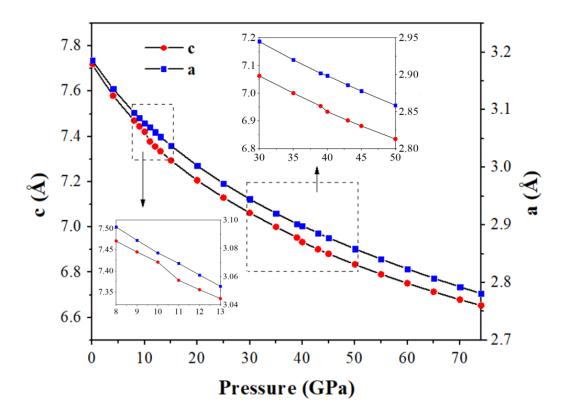


Figure S1. Plot of the lattice constants (*a* and *c*) *versus* pressure (0-74 GPa). Insets represent the enlargement in the rectangular dashed lines.

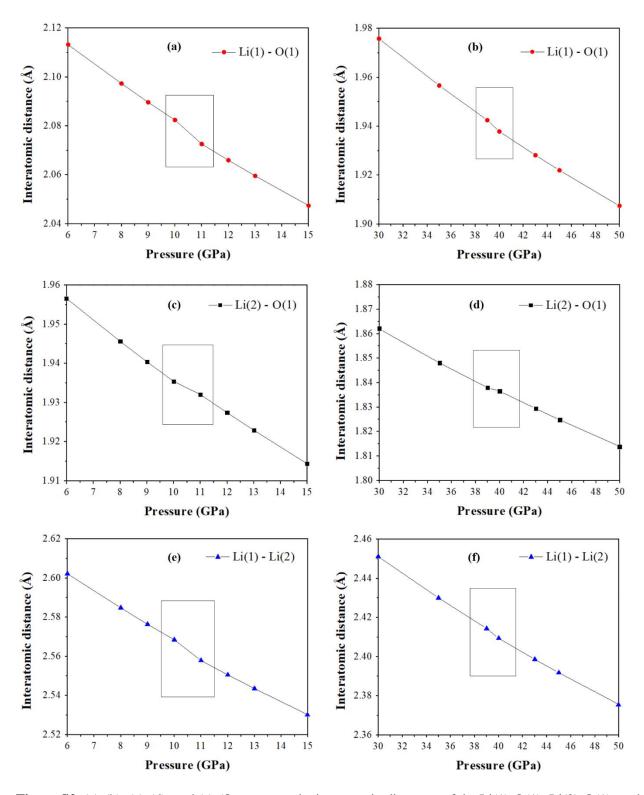


Figure S2. (a)-(b), (c)-(d), and (e)-(f) represent the interatomic distances of the Li(1)-O(1), Li(2)-O(1), and Li(1)-Li(2) in the pressure ranges of 6-15 GPa and 30-50 GPa, respectively. The rectangular solid lines mark the abnormal change of the interatomic distances in the pressure ranges of 10-11 GPa and 39-40 GPa.

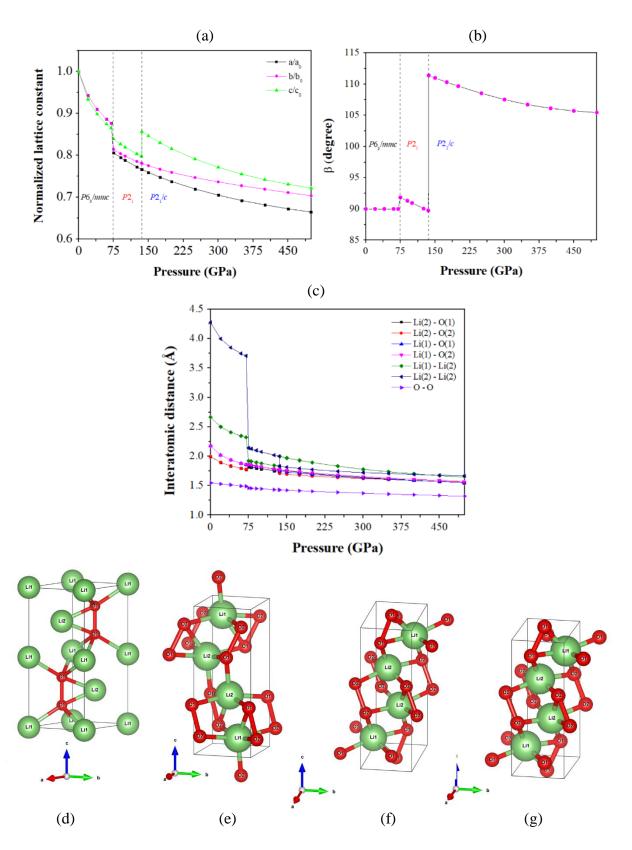


Figure S3. (a) Plot of the normalized lattice constants *versus* pressure, (b) Plot of the β *versus* pressure, (c) Plot of the interatomic distance *versus* pressure, (d) the $P6_3/mmc$ structure at 0 GPa, (e) the $P2_1/c$ structure at 75 GPa, (f) the $P2_1/c$ structure at 150 GPa, and (g) the $P2_1/c$ structure at 500 GPa.

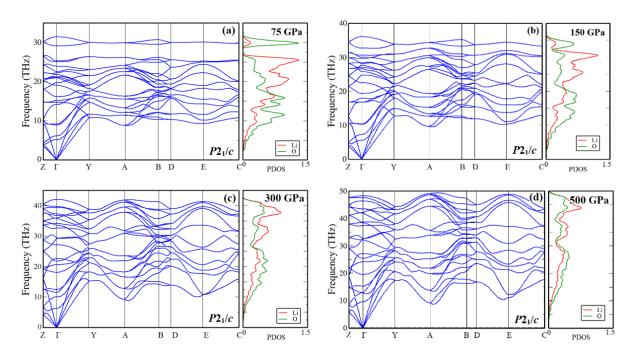


Figure S4. Phonon dispersion curves and partial phonon density of states (PDOSs) for the $P2_1/c$ structure at pressures of: (a)-(d) 75, 150, 300, and 500 GPa, respectively.

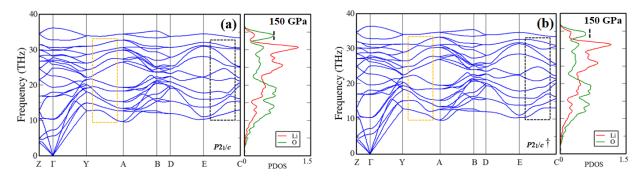
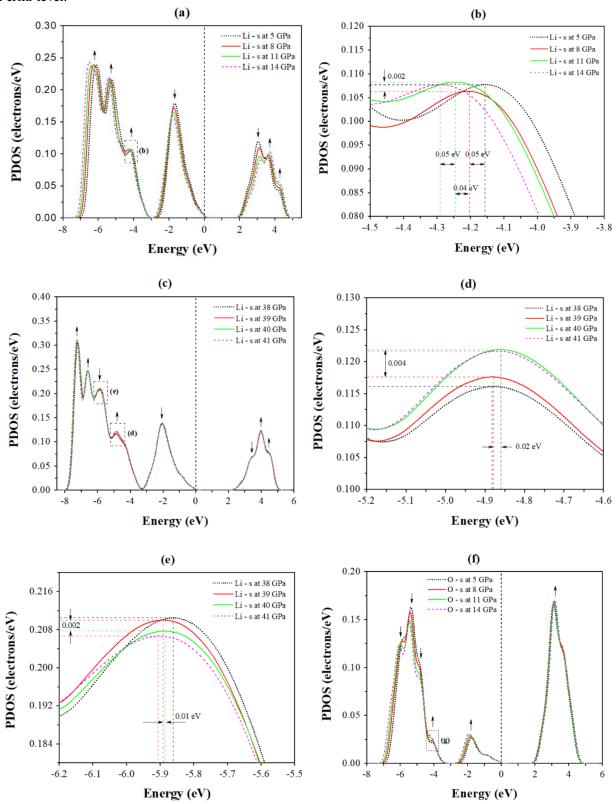
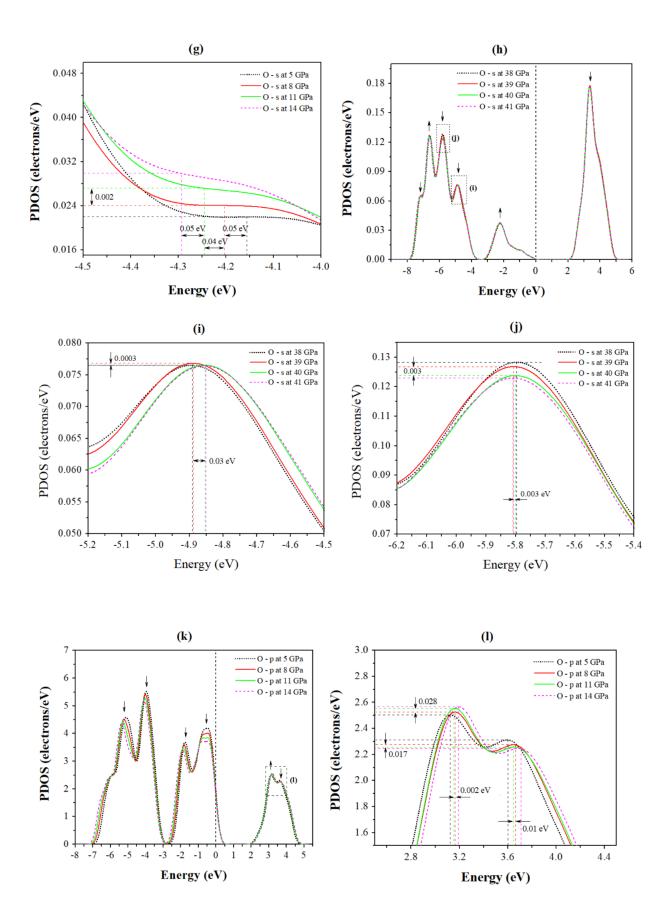
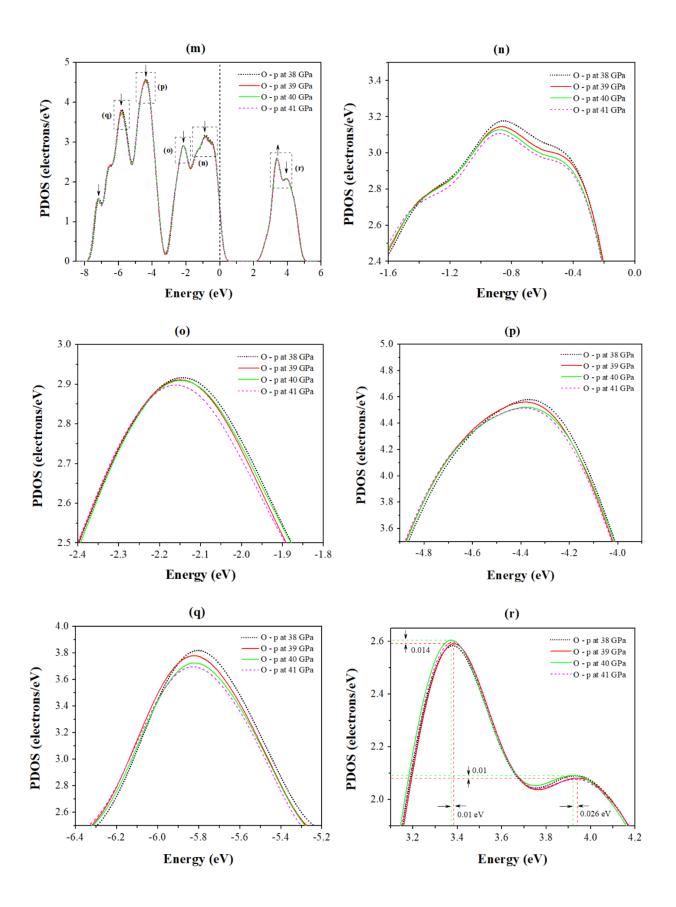


Figure S5. Phonon dispersion curves and partial phonon density of states (PDOSs) for two structures of Li_2O_2 at 150 GPa: (a) the $P2_1/c$ structure, and (b) the $P2_1/c^{\dagger}$ structure. The yellow and black rectangular dashed lines represent the differences between the $P2_1/c$ and $P2_1/c^{\dagger}$ structure in the Y-A and E-C paths, respectively. The vertical dashed lines mark the peak of the highest frequency phonon modes in the $P2_1/c$ structures.

Figure S6. Partial density of states (PDOSs) of Li and O for the *P6*₃/*mmc* structure at 5, 8, 11, 14, 38, 39, 40, and 41 GPa: (a)-(e) for the s-states of Li, (f)-(j) for the s-states of O, and (k)-(r) for the p-states of O. The arrows represent the trends of changes with increasing pressure. The vertical dashed lines represent the Fermi level.







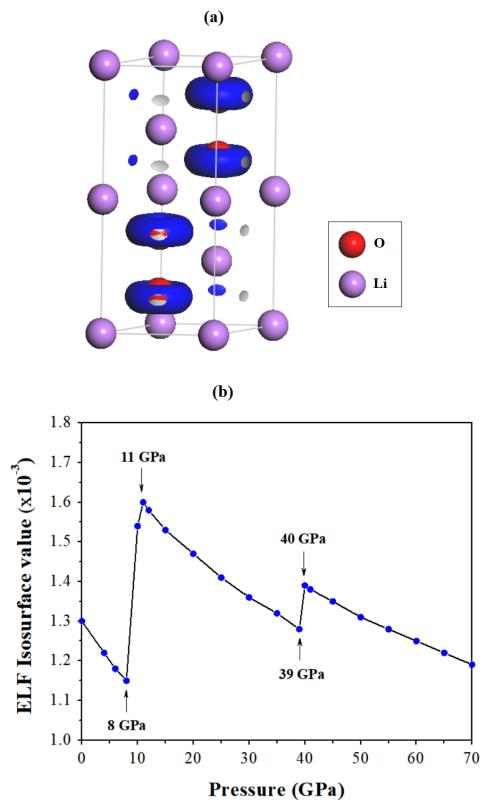


Figure S7. (a) Isosurface of the electron localization functions (ELF) in the $P6_3/mmc$ structure at 40 GPa. (b) Plot of the ELF isosurface value for the $P6_3/mmc$ structure in the pressure range of 0-70 GPa.

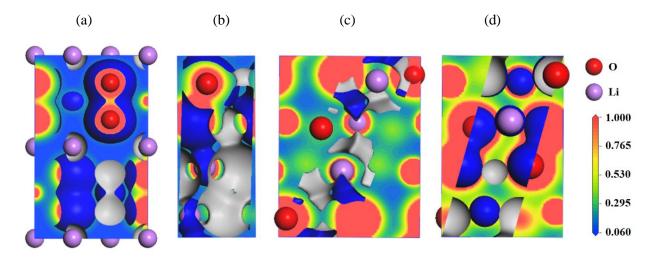


Figure S8. Electron density maps of various structures of Li_2O_2 projected onto (020) plane of: (a) the $P6_3/mmc$ structure at 0 GPa, (b) the $P2_1$ structure at 75 GPa, (c)-(d) the $P2_1/c$ structure at 150 and 500 GPa, respectively. The electron density isosurfaces values of 0.200 for (a, b, c) and 1.412 for (d).

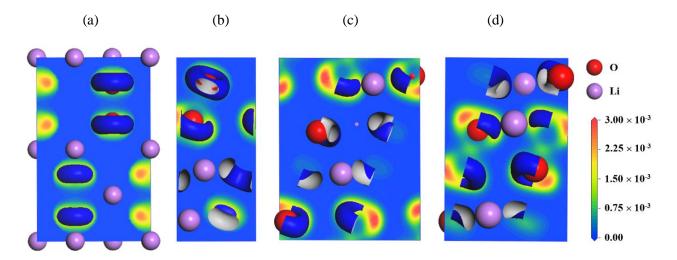


Figure S9. ELFs for various structures of Li_2O_2 projected onto (020) plane of: (a) the $P6_3/mmc$ structure at 0 GPa, (b) the $P2_1$ structure at 75 GPa, (c)-(d) the $P2_1/c$ structure at 150 and 500 GPa, respectively. The ELF isosurface values of 0.001 for (a) and 0.002 for (b, c, d).

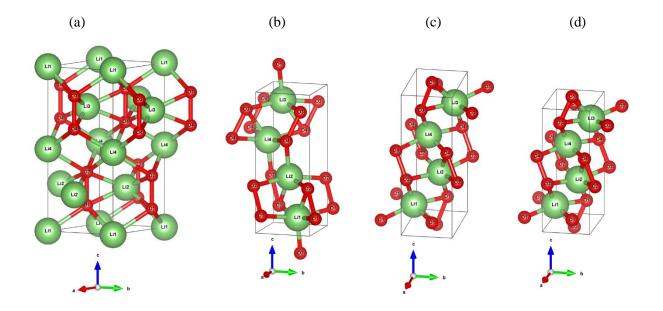


Figure S10. Crystal structures of Li₂O₂ for three phases at the different pressures: (a) the $P6_3/mmc$ structure at 0 GPa, (b) the $P2_1$ structure at 75 GPa, (c)-(d) the $P2_1/c$ structure at 150 and 500 GPa, respectively.